

# TLC225x-Q1, TLC225xA-Q1 Advanced LinCMOS™ RAIL-TO-RAIL VERY LOW-POWER OPERATIONAL AMPLIFIERS

SGLS188B – OCTOBER 2003 – REVISED APRIL 2008

- Qualified for Automotive Applications
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 150 V (TLC2252/52A) and 100 V (TLC2254/54A) Using Machine Model (C = 200 pF, R = 0)
- Output Swing Includes Both Supply Rails
- Low Noise . . . 19 nV/√Hz Typ at f = 1 kHz
- Low Input Bias Current . . . 1 pA Typ
- Fully Specified for Both Single-Supply and Split-Supply Operation
- Very Low Power . . . 35 μA Per Channel Typ
- Common-Mode Input Voltage Range Includes Negative Rail
- Low Input Offset Voltage  
850 μV Max at T<sub>A</sub> = 25°C (TLC225xA)
- Macromodel Included
- Performance Upgrades for the TS27L2/L4 and TLC27L2/L4

## description

The TLC2252 and TLC2254 are dual and quadruple operational amplifiers from Texas Instruments. Both devices exhibit rail-to-rail output performance for increased dynamic range in single- or split-supply applications. The TLC225x family consumes only 35 μA of supply current per channel. This micropower operation makes them good choices for battery-powered applications. The noise performance has been dramatically improved over previous generations of CMOS amplifiers. Looking at Figure 1, the TLC225x has a noise level of 19 nV/√Hz at 1 kHz; four times lower than competitive micropower solutions.

The TLC225x amplifiers, exhibiting high input impedance and low noise, are excellent for small-signal conditioning for high-impedance sources, such as piezoelectric transducers. Because of the micropower dissipation levels, these devices work well in hand-held monitoring and remote-sensing applications. In addition, the rail-to-rail output feature with single or split supplies makes this family a great choice when interfacing with analog-to-digital converters (ADCs). For precision applications, the TLC225xA family is available and has a maximum input offset voltage of 850 μV. This family is fully characterized at 5 V and ±5 V.

The TLC2252/4 also makes great upgrades to the TLC27L2/L4 or TS27L2/L4 in standard designs. They offer increased output dynamic range, lower noise voltage, and lower input offset voltage. This enhanced feature set allows them to be used in a wider range of applications. For applications that require higher output drive and wider input voltage ranges, see the TLV2432 and TLV2442 devices. If the design requires single amplifiers, please see the TLV2211/21/31 family. These devices are single rail-to-rail operational amplifiers in the SOT-23 package. Their small size and low power consumption, make them ideal for high density, battery-powered equipment.

EQUIVALENT INPUT NOISE VOLTAGE  
vs  
FREQUENCY

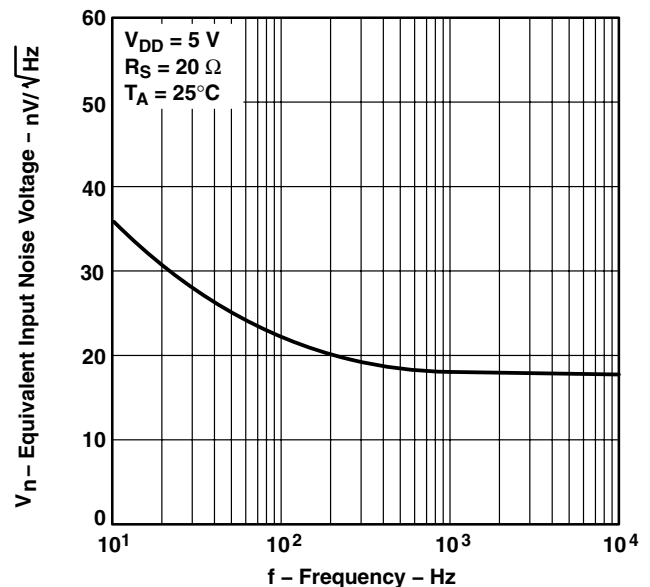


Figure 1



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

 **TEXAS  
INSTRUMENTS**

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# TLC225x-Q1, TLC225xA-Q1

## Advanced LinCMOS™ RAIL-TO-RAIL

### VERY LOW-POWER OPERATIONAL AMPLIFIERS

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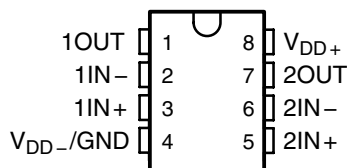
#### ORDERING INFORMATION†

T <sub>A</sub>	V <sub>IO</sub> max AT 25°C	PACKAGE‡		ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 125°C	850 µV	SOIC (D)	Tape and reel	TLC2252AQDRQ1	2252AQ
		TSSOP (PW)	Tape and reel	TLC2252AQPWRQ1	2252AQ
	1550 µV	SOIC (D)	Tape and reel	TLC2252QDRQ1	2252Q1
		TSSOP (PW)	Tape and reel	TLC2252QPWRQ1	2252Q1
	850 µV	SOIC (D)	Tape and reel	TLC2254AQDRQ1	TLC2254AQ1
		TSSOP (PW)	Tape and reel	TLC2254AQPWRQ1	2254AQ
	1550 µV	SOIC (D)	Tape and reel	TLC2254QDRQ1	TLC2254Q1
		TSSOP (PW)	Tape and reel	TLC2254QPWRQ1	2254Q1

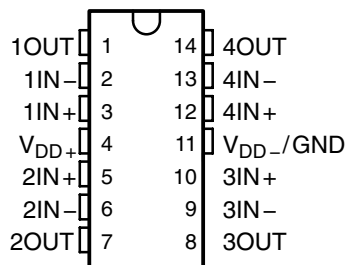
† For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at <http://www.ti.com>.

‡ Package drawings, thermal data, and symbolization are available at <http://www.ti.com/packaging>.

**TLC2252, TLC2252A**  
D OR PW PACKAGE  
(TOP VIEW)



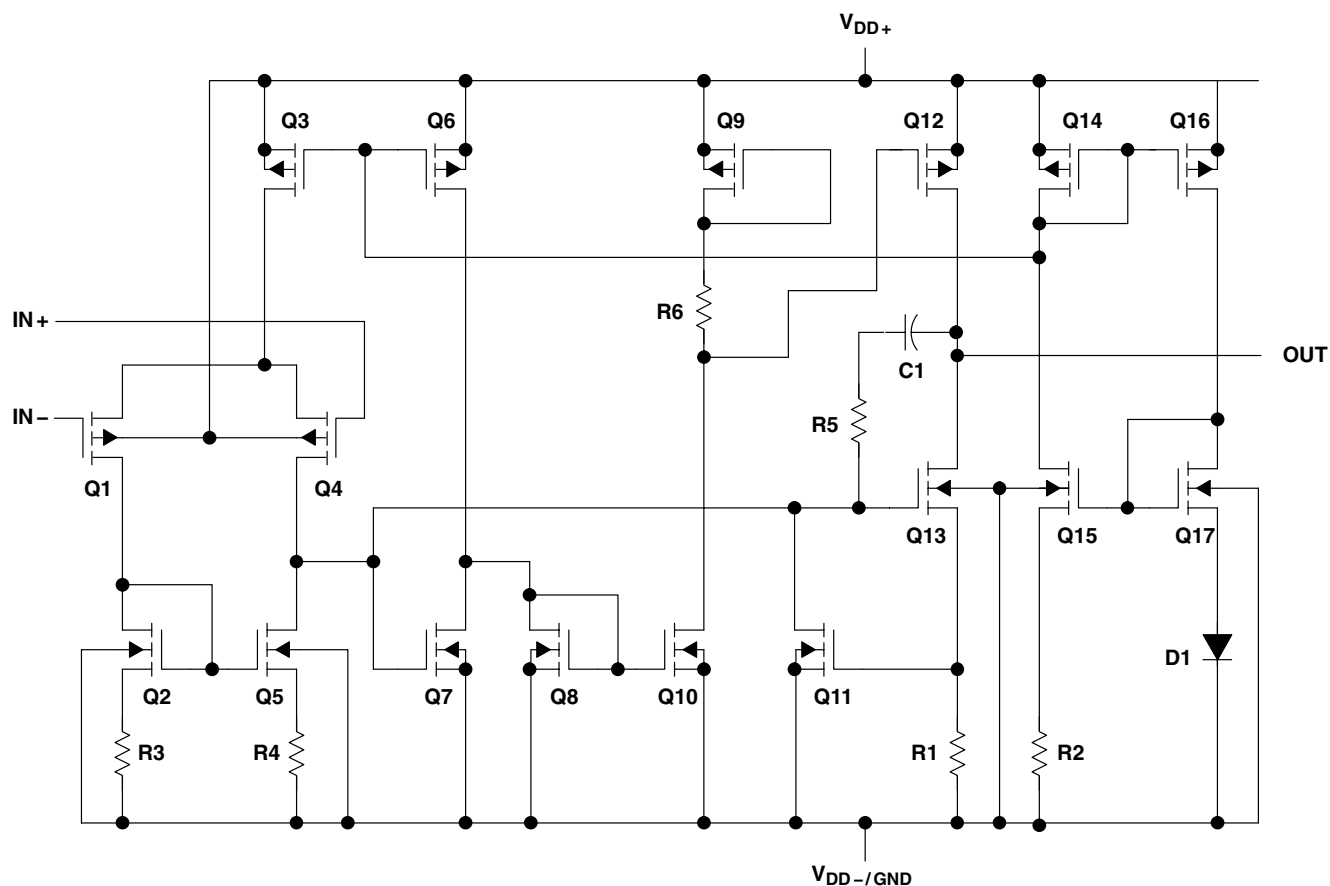
**TLC2254, TLC2254A**  
D OR PW PACKAGE  
(TOP VIEW)



**TLC225x-Q1, TLC225xA-Q1**  
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equivalent schematic (each amplifier)



ACTUAL DEVICE COMPONENT COUNT†		
COMPONENT	TLC2252	TLC2254
Transistors	38	76
Resistors	30	56
Diodes	9	18
Capacitors	3	6

† Includes both amplifiers and all ESD, bias, and trim circuitry



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**absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†**

Supply voltage, $V_{DD+}$ (see Note 1)	8 V
Supply voltage, $V_{DD-}$ (see Note 1)	-8 V
Differential input voltage, $V_{ID}$ (see Note 2)	$\pm 16$ V
Input voltage, $V_I$ (any input, see Note 1)	$\pm 8$ V
Input current, $I_I$ (each input)	$\pm 5$ mA
Output current, $I_O$	$\pm 50$ mA
Total current into $V_{DD+}$	$\pm 50$ mA
Total current out of $V_{DD-}$	$\pm 50$ mA
Duration of short-circuit current at (or below) 25°C (see Note 3)	unlimited
Continuous total dissipation	See Dissipation Rating Table
Operating free-air temperature range, $T_A$ : Q suffix	-40°C to 125°C
Storage temperature range, $T_{stg}$	-65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between  $V_{DD+}$  and  $V_{DD-}$ .  
 2. Differential voltages are at  $IN+$  with respect to  $IN-$ . Excessive current flows when input is brought below  $V_{DD-} - 0.3$  V.  
 3. The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.

**DISSIPATION RATING TABLE**

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING	$T_A = 125^\circ\text{C}$ POWER RATING
D-8	724 mW	5.8 mW/°C	464 mW	377 mW	144 mW
D-14	950 mW	7.6 mW/°C	608 mW	450 mW	190 mW
PW-8	525 mW	4.2 mW/°C	336 mW	273 mW	105 mW
PW-14	700 mW	5.6 mW/°C	448 mW	364 mW	140 mW

**recommended operating conditions**

	MIN	MAX	UNIT
Supply voltage, $V_{DD\pm}$	$\pm 2.2$	$\pm 8$	V
Input voltage range, $V_I$	$V_{DD-}$	$V_{DD+} - 1.5$	V
Common-mode input voltage, $V_{IC}$	$V_{DD-}$	$V_{DD+} - 1.5$	V
Operating free-air temperature, $T_A$	-40	125	°C

‡ Referenced to 2.5 V



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**electrical characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2252-Q1			TLC2252A-Q1			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{IO}$ Input offset voltage		25°C	200	1500		200	850	$\mu\text{V}$	
		Full range		1750		1000			
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		25°C to 125°C	0.5			0.5			$\mu\text{V}/^\circ\text{C}$
Input offset voltage long-term drift (see Note 4)	$V_{DD\pm} = \pm 2.5\text{ V}$ , $V_O = 0$ ,	25°C	0.003			0.003			$\mu\text{V}/\text{mo}$
$I_{IO}$ Input offset current		25°C	0.5	60		0.5	60	$\text{pA}$	
		Full range		1000		1000			
$I_{IB}$ Input bias current		25°C	1	60		1	60	$\text{pA}$	
		Full range		1000		1000			
$V_{ICR}$ Common-mode input voltage range	$R_S = 50\ \Omega$ , $ V_{IO}  \leq 5\text{ mV}$	25°C	0 to 4	-0.3 to 4.2		0 to 4	-0.3 to 4.2	$\text{V}$	
		Full range	0 to 3.5			0 to 3.5			
$V_{OH}$ High-level output voltage	$I_{OH} = -20\ \mu\text{A}$	25°C	4.98			4.98			$\text{V}$
	$I_{OH} = -75\ \mu\text{A}$	25°C	4.9	4.94		4.9	4.94		
	Full range		4.8			4.8			
$V_{OL}$ Low-level output voltage	$V_{IC} = 2.5\text{ V}$ , $I_{OL} = 50\ \mu\text{A}$	25°C	0.01			0.01			$\text{V}$
	$V_{IC} = 2.5\text{ V}$ , $I_{OL} = 500\ \mu\text{A}$	25°C	0.09	0.15		0.09	0.15		
	Full range			0.15			0.15		
	$V_{IC} = 2.5\text{ V}$ , $I_{OL} = 4\text{ mA}$	25°C	0.8	1		0.7	1		
$A_{VD}$ Large-signal differential voltage amplification	$V_{IC} = 2.5\text{ V}$ , $V_O = 1\text{ V to }4\text{ V}$	$R_L = 100\text{ k}\Omega^\ddagger$	25°C	100	350		100	350	$\text{V}/\text{mV}$
		Full range		10			10		
		$R_L = 1\text{ M}\Omega^\ddagger$	25°C	1700			1700		
$r_{id}$ Differential input resistance		25°C	$10^{12}$			$10^{12}$			$\Omega$
$r_{ic}$ Common-mode input resistance		25°C	$10^{12}$			$10^{12}$			$\Omega$
$c_{ic}$ Common-mode input capacitance	$f = 10\text{ kHz}$ , $f = 10\text{ kHz}$ ,	25°C	8			8			$\text{pF}$
$z_o$ Closed-loop output impedance	$f = 25\text{ kHz}$ , $A_V = 10$	25°C	200			200			$\Omega$
CMRR Common-mode rejection ratio	$V_{IC} = 0\text{ to }2.7\text{ V}$ , $V_O = 2.5\text{ V}$ , $R_S = 50\ \Omega$	25°C	70	83		70	83	$\text{dB}$	
		Full range		70			70		
$k_{SVR}$ Supply-voltage rejection ratio ( $\Delta V_{DD}/\Delta V_{IO}$ )	$V_{DD} = 4.4\text{ V to }16\text{ V}$ , $V_{IC} = V_{DD}/2$ , No load	25°C	80	95		80	95	$\text{dB}$	
		Full range		80			80		
$I_{DD}$ Supply current	$V_O = 2.5\text{ V}$ , No load	25°C	70	125		70	125	$\mu\text{A}$	
		Full range		150			150		

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q suffix.

‡ Referenced to 2.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.



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**operating characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$**

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2252-Q1			TLC2252A-Q1			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain $V_O = 0.5\text{ V to }3.5\text{ V}$ , $R_L = 100\text{ k}\Omega^\ddagger$ , $C_L = 100\text{ pF}^\ddagger$	25°C	0.07	0.12		0.07	0.12		V/ $\mu$ s
		Full range	0.05			0.05			
$V_n$	Equivalent input noise voltage $f = 10\text{ Hz}$ $f = 1\text{ kHz}$	25°C	36			36			nV/ $\sqrt{\text{Hz}}$
		25°C	19			19			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage $f = 0.1\text{ Hz to }1\text{ Hz}$ $f = 0.1\text{ Hz to }10\text{ Hz}$	25°C	0.7			0.7			$\mu$ V
		25°C	1.1			1.1			
$I_n$	Equivalent input noise current	25°C	0.6			0.6			fA/ $\sqrt{\text{Hz}}$
THD + N	Total harmonic distortion plus noise $V_O = 0.5\text{ V to }2.5\text{ V}$ , $f = 10\text{ kHz}$ , $R_L = 50\text{ k}\Omega^\ddagger$	25°C	$A_V = 1$			0.2%			
			$A_V = 10$			1%			
	Gain-bandwidth product $f = 50\text{ kHz}$ , $C_L = 100\text{ pF}^\ddagger$	25°C	$R_L = 50\text{ k}\Omega^\ddagger$			0.2			MHz
BOM	Maximum output-swing bandwidth $V_{O(PP)} = 2\text{ V}$ , $R_L = 50\text{ k}\Omega^\ddagger$	25°C	$A_V = 1$ , $C_L = 100\text{ pF}^\ddagger$			30			kHz
$\phi_m$	Phase margin at unity gain $R_L = 50\text{ k}\Omega^\ddagger$ , $C_L = 100\text{ pF}^\ddagger$	25°C	63°			63°			
		25°C	15			15			dB

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q suffix.

‡ Referenced to 2.5 V



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**electrical characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLC2252-Q1			TLC2252A-Q1			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
$V_{IO}$ Input offset voltage	$V_{IC} = 0, V_O = 0, R_S = 50\ \Omega$	25°C	200		1500	200		850	$\mu\text{V}$	
		Full range	1750			1000				
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		25°C to 125°C	0.5			0.5			$\mu\text{V}/^\circ\text{C}$	
Input offset voltage long-term drift (see Note 4)		25°C	0.003			0.003			$\mu\text{V}/\text{mo}$	
$I_{IO}$ Input offset current		25°C	0.5	60		0.5	60		$\text{pA}$	
		Full range	1000			1000				
$I_{IB}$ Input bias current	25°C	1	60		1	60		$\text{pA}$		
	Full range	1000			1000					
$V_{ICR}$ Common-mode input voltage range	$R_S = 50\ \Omega,  V_{IO}  \leq 5\ \text{mV}$	25°C	-5 to 4	-5.3 to 4.2		-5 to 4	-5.3 to 4.2	$\text{V}$		
		Full range	-5 to 3.5			-5 to 3.5				
$V_{OM+}$ Maximum positive peak output voltage	$I_O = -20\ \mu\text{A}$	25°C	4.98			4.98			$\text{V}$	
		25°C	4.9	4.93		4.9	4.93			
		Full range	4.7			4.7				
		25°C	4.8	4.86		4.8	4.86			
$V_{OM-}$ Maximum negative peak output voltage	$V_{IC} = 0, I_O = 50\ \mu\text{A}$	25°C	-4.99			-4.99			$\text{V}$	
		25°C	-4.85	-4.91		-4.85	-4.91			
	Full range	-4.85			-4.85					
	$V_{IC} = 0, I_O = 4\ \text{mA}$	25°C	-4	-4.3		-4	-4.3			
		Full range	-3.8			-3.8				
	$A_{VD}$ Large-signal differential voltage amplification	$V_O = \pm 4\ \text{V}$	$R_L = 100\ \text{k}\Omega$	25°C	40	150		40		150
Full range				10			10			
$R_L = 1\ \text{M}\Omega$			25°C	3000			3000			
$r_{id}$ Differential input resistance		25°C	$10^{12}$			$10^{12}$			$\Omega$	
$r_{ic}$ Common-mode input resistance		25°C	$10^{12}$			$10^{12}$			$\Omega$	
$c_{ic}$ Common-mode input capacitance	$f = 10\ \text{kHz}, \text{ P package}$	25°C	8			8			$\text{pF}$	
$z_o$ Closed-loop output impedance	$f = 25\ \text{kHz}, A_V = 10$	25°C	190			190			$\Omega$	
CMRR Common-mode rejection ratio	$V_{IC} = -5\ \text{V to } 2.7\ \text{V}, V_O = 0, R_S = 50\ \Omega$	25°C	75	88		75	88		$\text{dB}$	
		Full range	75			75				
$k_{SVR}$ Supply-voltage rejection ratio ( $\Delta V_{DD\pm}/\Delta V_{IO}$ )	$V_{DD} = \pm 2.2\ \text{V to } \pm 8\ \text{V}, V_{IC} = 0, \text{ No load}$	25°C	80	95		80	95		$\text{dB}$	
		Full range	80			80				
$I_{DD}$ Supply current	$V_O = 2.5\ \text{V}, \text{ No load}$	25°C	80	125		80	125		$\mu\text{A}$	
		Full range	150			150				

$^\dagger$  Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q suffix.

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.



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operating characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\text{ V}$

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLC2252-Q1			TLC2252A-Q1			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
SR	Slew rate at unity gain $V_O = \pm 2\text{ V}$ , $C_L = 100\text{ pF}$ , $R_L = 100\text{ k}\Omega$	25°C	0.07	0.12		0.07	0.12		$\text{V}/\mu\text{s}$	
		Full range	0.05			0.05				
$V_n$	Equivalent input noise voltage	f = 10 Hz	38			38			$\text{nV}/\sqrt{\text{Hz}}$	
		f = 1 kHz	19			19				
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 1 Hz	0.8			0.8			$\mu\text{V}$	
		f = 0.1 Hz to 10 Hz	1.1			1.1				
$I_n$	Equivalent input noise current	25°C	0.6			0.6			$\text{fA}/\sqrt{\text{Hz}}$	
THD + N	Total harmonic distortion plus noise	$V_O = \pm 2.3\text{ V}$ , $R_L = 50\text{ k}\Omega$ , f = 10 kHz	$A_V = 1$	0.2%			0.2%			
			$A_V = 10$	1%			1%			
	Gain-bandwidth product	f = 10 kHz, $C_L = 100\text{ pF}$ , $R_L = 50\text{ k}\Omega$	25°C	0.21			0.21			MHz
BOM	Maximum output-swing bandwidth	$V_{O(PP)} = 4.6\text{ V}$ , $R_L = 50\text{ k}\Omega$ , $C_L = 100\text{ pF}$	25°C	14			14			kHz
$\phi_m$	Phase margin at unity gain	$R_L = 50\text{ k}\Omega$ , $C_L = 100\text{ pF}$	25°C	63°			63°			
	Gain margin		25°C	15			15			dB

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q suffix.





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**electrical characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLC2254-Q1			TLC2254A-Q1			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
$V_{IO}$ Input offset voltage		25°C	200		1500	200		850	$\mu\text{V}$	
		Full range	1750			1000				
$\alpha_{VIO}$ Temperature coefficient of input offset voltage	$V_{DD\pm} = \pm 2.5\text{ V}$ , $V_{IC} = 0$ , $V_O = 0$ , $R_S = 50\ \Omega$	25°C to 125°C	0.5			0.5			$\mu\text{V}/^\circ\text{C}$	
Input offset voltage long-term drift (see Note 4)		25°C	0.003			0.003			$\mu\text{V}/\text{mo}$	
$I_{IO}$ Input offset current		25°C	0.5	60		0.5	60		$\text{pA}$	
		125°C	1000			1000				
$I_{IB}$ Input bias current	25°C	1	60		1	60		$\text{pA}$		
	125°C	1000			1000					
$V_{ICR}$ Common-mode input voltage range	$R_S = 50\ \Omega$ , $ V_{IO}  \leq 5\text{ mV}$	25°C	0 to 4	-0.3 to 4.2	0 to 4	-0.3 to 4.2			$\text{V}$	
		Full range	0 to 3.5		0 to 3.5					
$V_{OH}$ High-level output voltage	$I_{OH} = -20\ \mu\text{A}$	25°C	4.98		4.98				$\text{V}$	
	$I_{OH} = -75\ \mu\text{A}$	25°C	4.9	4.94		4.9	4.94			
	Full range	4.8			4.8					
$V_{OL}$ Low-level output voltage	$V_{IC} = 2.5\text{ V}$ , $I_{OL} = 50\ \mu\text{A}$	25°C	0.01			0.01			$\text{V}$	
	$V_{IC} = 2.5\text{ V}$ , $I_{OL} = 500\ \mu\text{A}$	25°C	0.09	0.15		0.09	0.15			
	Full range	0.15			0.15					
	$V_{IC} = 2.5\text{ V}$ , $I_{OL} = 4\text{ mA}$	25°C	0.8	1		0.7	1			
	Full range	1.2			1.2					
$A_{VD}$ Large-signal differential voltage amplification	$V_{IC} = 2.5\text{ V}$ , $V_O = 1\text{ V to }4\text{ V}$	$R_L = 100\text{ k}\Omega^\ddagger$	25°C	100	350		100	350		$\text{V/mV}$
			Full range	10			10			
		$R_L = 1\text{ M}\Omega^\ddagger$	25°C	1700			1700			
$r_{i(d)}$ Differential input resistance		25°C	$10^{12}$			$10^{12}$			$\Omega$	
$r_{i(c)}$ Common-mode input resistance		25°C	$10^{12}$			$10^{12}$			$\Omega$	
$C_{i(c)}$ Common-mode input capacitance	$f = 10\text{ kHz}$ , N package	25°C	8			8			$\text{pF}$	
$z_o$ Closed-loop output impedance	$f = 25\text{ kHz}$ , $A_V = 10$	25°C	200			200			$\Omega$	
CMRR Common-mode rejection ratio	$V_{IC} = 0\text{ to }2.7\text{ V}$ , $V_O = 2.5\text{ V}$ , $R_S = 50\ \Omega$	25°C	70	83		70	83		$\text{dB}$	
		Full range	70			70				
$k_{SVR}$ Supply-voltage rejection ratio ( $\Delta V_{DD}/\Delta V_{IO}$ )	$V_{DD} = 4.4\text{ V to }16\text{ V}$ , $V_{IC} = V_{DD}/2$ , No load	25°C	80	95		80	95		$\text{dB}$	
		Full range	80			80				
$I_{DD}$ Supply current (four amplifiers)	$V_O = 2.5\text{ V}$ , No load	25°C	140	250		140	250		$\mu\text{A}$	
		Full range	300			300				

$^\dagger$  Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q suffix.

$^\ddagger$  Referenced to 2.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.



**TLC225x-Q1, TLC225xA-Q1**  
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operating characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$

PARAMETER	TEST CONDITIONS	$T_A$ †	TLC2254-Q1			TLC2254A-Q1			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain $V_O = 0.5\text{ V to }3.5\text{ V}$ , $R_L = 100\text{ k}\Omega^\ddagger$ , $C_L = 100\text{ pF}^\ddagger$	25°C	0.07	0.12		0.07	0.12		V/ $\mu$ s
		Full range	0.05			0.05			
$V_n$	Equivalent input noise voltage $f = 10\text{ Hz}$ $f = 1\text{ kHz}$	25°C	36			36			nV/ $\sqrt{\text{Hz}}$
		25°C	19			19			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage $f = 0.1\text{ Hz to }1\text{ Hz}$ $f = 0.1\text{ Hz to }10\text{ Hz}$	25°C	0.7			0.7			$\mu$ V
		25°C	1.1			1.1			
$I_n$	Equivalent input noise current	25°C	0.6			0.6			fA/ $\sqrt{\text{Hz}}$
THD + N	Total harmonic distortion plus noise $V_O = 0.5\text{ V to }2.5\text{ V}$ , $f = 20\text{ kHz}$ , $R_L = 50\text{ k}\Omega^\ddagger$	25°C	$A_V = 1$			0.2%			
			$A_V = 10$			1%			
	Gain-bandwidth product $f = 50\text{ kHz}$ , $C_L = 100\text{ pF}^\ddagger$	$R_L = 50\text{ k}\Omega^\ddagger$ , 25°C	0.2			0.2			MHz
$B_{OM}$	Maximum output-swing bandwidth $V_{O(PP)} = 2\text{ V}$ , $R_L = 50\text{ k}\Omega^\ddagger$	$A_V = 1$ , $C_L = 100\text{ pF}^\ddagger$ , 25°C	30			30			kHz
$\phi_m$	Phase margin at unity gain $R_L = 50\text{ k}\Omega^\ddagger$	$C_L = 100\text{ pF}^\ddagger$ , 25°C	63°			63°			
			15			15			dB

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q suffix.

‡ Referenced to 2.5 V



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**electrical characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\text{ V}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLC2254-Q1			TLC2254A-Q1			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{IO}$ Input offset voltage		25°C	200		1500	200		850	$\mu\text{V}$
		Full range	1750			1000			
$\alpha_{VIO}$ Temperature coefficient of input offset voltage		25°C to 125°C	0.5			0.5			$\mu\text{V}/^\circ\text{C}$
Input offset voltage long-term drift (see Note 4)	$V_{IC} = 0, V_O = 0, R_S = 50\ \Omega$	25°C	0.003			0.003			$\mu\text{V}/\text{mo}$
$I_{IO}$ Input offset current		25°C	0.5	60		0.5	60		$\text{pA}$
		125°C	1000			1000			
$I_{IB}$ Input bias current		25°C	1	60		1	60		$\text{pA}$
		125°C	1000			1000			
$V_{ICR}$ Common-mode input voltage range		$R_S = 50\ \Omega,  V_{IO}  \leq 5\ \text{mV}$	25°C	-5 to 4	-5.3 to 4.2		-5 to 4	-5.3 to 4.2	$\text{V}$
	Full range		-5 to 3.5			-5 to 3.5			
$V_{OM+}$ Maximum positive peak output voltage	$I_O = -20\ \mu\text{A}$	25°C	4.98		4.98		$\text{V}$		
		25°C	4.9	4.93		4.9		4.93	
		Full range	4.7			4.7			
		25°C	4.8	4.86		4.8		4.86	
$V_{OM-}$ Maximum negative peak output voltage	$V_{IC} = 0, I_O = 50\ \mu\text{A}$	25°C	-4.99		-4.99		$\text{V}$		
		25°C	-4.85	-4.91		-4.85		-4.91	
		Full range	-4.85			-4.85			
		25°C	-4	-4.3		-4		-4.3	
$V_{OM-}$ Maximum negative peak output voltage	$V_{IC} = 0, I_O = 500\ \mu\text{A}$	25°C	-4.99		-4.99		$\text{V}$		
		25°C	-4.85	-4.91		-4.85		-4.91	
		Full range	-4.85			-4.85			
		25°C	-4	-4.3		-4		-4.3	
$V_{OM-}$ Maximum negative peak output voltage	$V_{IC} = 0, I_O = 4\ \text{mA}$	25°C	-4.99		-4.99		$\text{V}$		
		25°C	-4.85	-4.91		-4.85		-4.91	
		Full range	-4.85			-4.85			
		25°C	-4	-4.3		-4		-4.3	
$A_{VD}$ Large-signal differential voltage amplification	$V_O = \pm 4\ \text{V}$	25°C	$R_L = 100\ \text{k}\Omega$	40	150	40	150	$\text{V}/\text{mV}$	
			Full range	10			10		
			$R_L = 1\ \text{M}\Omega$	3000			3000		
$r_{i(d)}$ Differential input resistance		25°C	$10^{12}$			$10^{12}$		$\Omega$	
$r_{i(c)}$ Common-mode input resistance		25°C	$10^{12}$			$10^{12}$		$\Omega$	
$c_{i(c)}$ Common-mode input capacitance	$f = 10\ \text{kHz}, \text{ N package}$	25°C	8			8		$\text{pF}$	
$z_o$ Closed-loop output impedance	$f = 25\ \text{kHz}, A_V = 10$	25°C	190			190		$\Omega$	
CMRR Common-mode rejection ratio	$V_{IC} = -5\ \text{V to } 2.7\ \text{V}, V_O = 0, R_S = 50\ \Omega$	25°C	75	88		75	88	$\text{dB}$	
		Full range	75			75			
$k_{SVR}$ Supply-voltage rejection ratio ( $\Delta V_{DD\pm}/\Delta V_{IO}$ )	$V_{DD\pm} = \pm 2.2\ \text{V to } \pm 8\ \text{V}, V_{IC} = V_{DD}/2, \text{ No load}$	25°C	80	95		80	95	$\text{dB}$	
		Full range	80			80			
$I_{DD}$ Supply current (four amplifiers)	$V_O = 0, \text{ No load}$	25°C	160	250		160	250	$\mu\text{A}$	
		Full range	300			300			

$^\dagger$  Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q suffix.

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.



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**operating characteristics at specified free-air temperature,  $V_{DD\pm} = \pm 5\text{ V}$**

PARAMETER	TEST CONDITIONS		$T_A^\dagger$	TLC2254-Q1			TLC2254A-Q1			UNIT	
				MIN	TYP	MAX	MIN	TYP	MAX		
SR	Slew rate at unity gain	$V_O = \pm 2\text{ V}$ , $C_L = 100\text{ pF}$	$R_L = 100\text{ k}\Omega$	25°C	0.07	0.12		0.07	0.12	$\text{V}/\mu\text{s}$	
				Full range	0.05			0.05			
$V_n$	Equivalent input noise voltage	$f = 10\text{ Hz}$		25°C	38			38			$\text{nV}/\sqrt{\text{Hz}}$
				$f = 1\text{ kHz}$		19			19		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$		25°C	0.8			0.8			$\mu\text{V}$
		$f = 0.1\text{ Hz to }10\text{ Hz}$		1.1			1.1				
$I_n$	Equivalent input noise current			25°C	0.6			0.6			$\text{fA}/\sqrt{\text{Hz}}$
THD + N	Total harmonic distortion plus noise	$V_O = \pm 2.3\text{ V}$ , $R_L = 50\text{ k}\Omega$ , $f = 20\text{ kHz}$	$A_V = 1$	25°C	0.2%			0.2%			
					$A_V = 10$	1%			1%		
	Gain-bandwidth product	$f = 10\text{ kHz}$ , $C_L = 100\text{ pF}$	$R_L = 50\text{ k}\Omega$	25°C	0.21			0.21			MHz
$B_{OM}$	Maximum output-swing bandwidth	$V_{O(PP)} = 4.6\text{ V}$ , $R_L = 50\text{ k}\Omega$	$A_V = 1$ , $C_L = 100\text{ pF}$	25°C	14			14			kHz
$\phi_m$	Phase margin at unity gain	$R_L = 50\text{ k}\Omega$	$C_L = 100\text{ pF}$	25°C	63°			63°			
	Gain margin			25°C	15			15			dB

† Full range is  $-40^\circ\text{C}$  to  $125^\circ\text{C}$  for Q suffix.

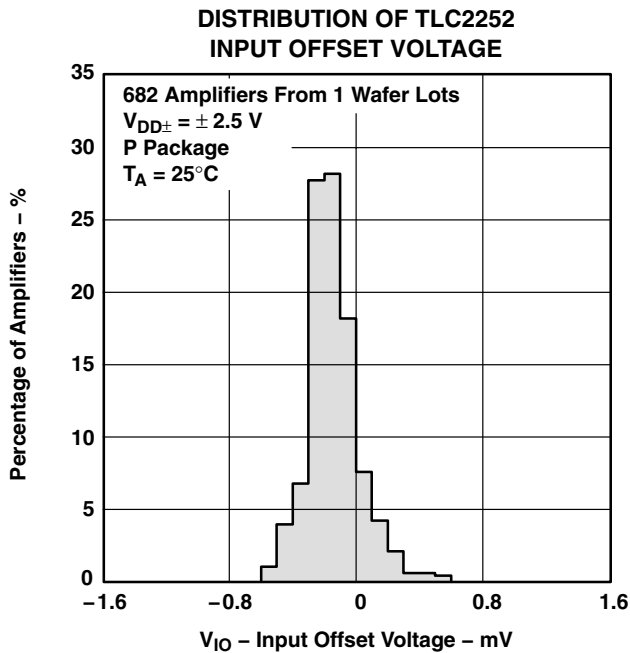


## TYPICAL CHARACTERISTICS

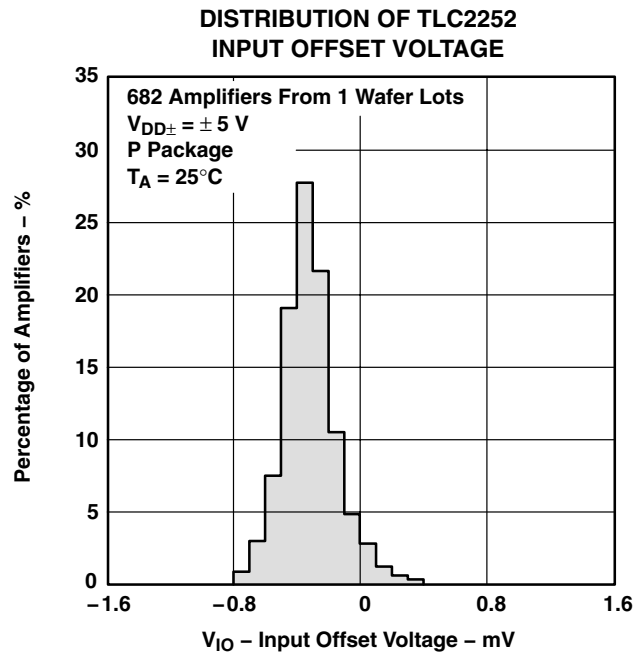
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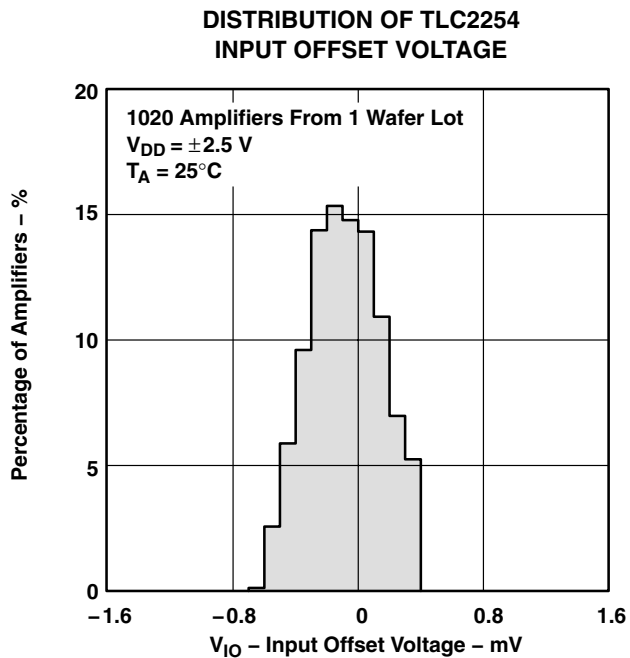
**TYPICAL CHARACTERISTICS**



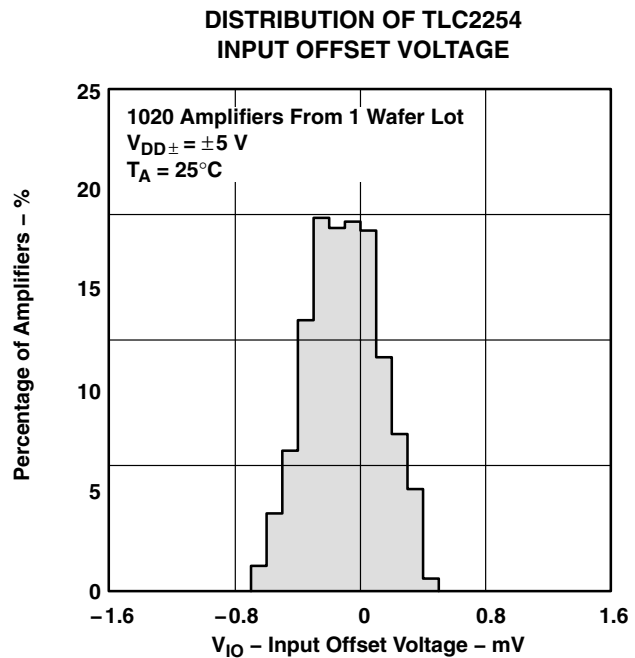
**Figure 2**



**Figure 3**



**Figure 4**



**Figure 5**

TYPICAL CHARACTERISTICS

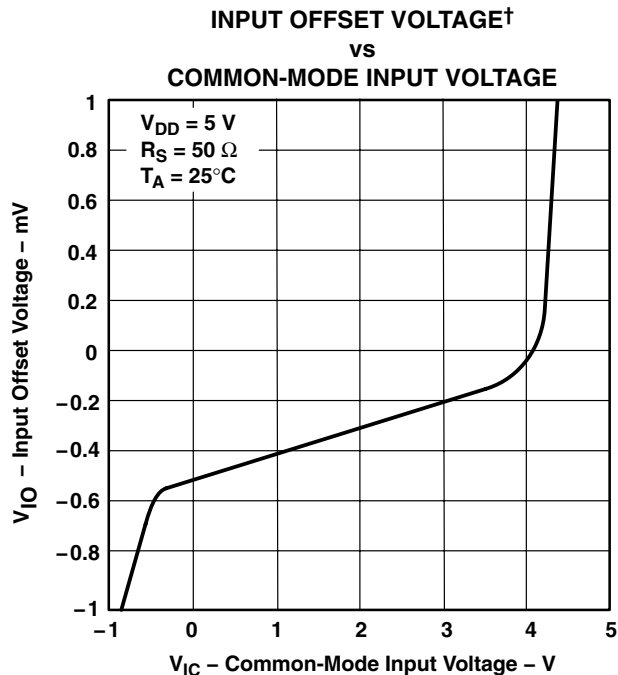


Figure 6

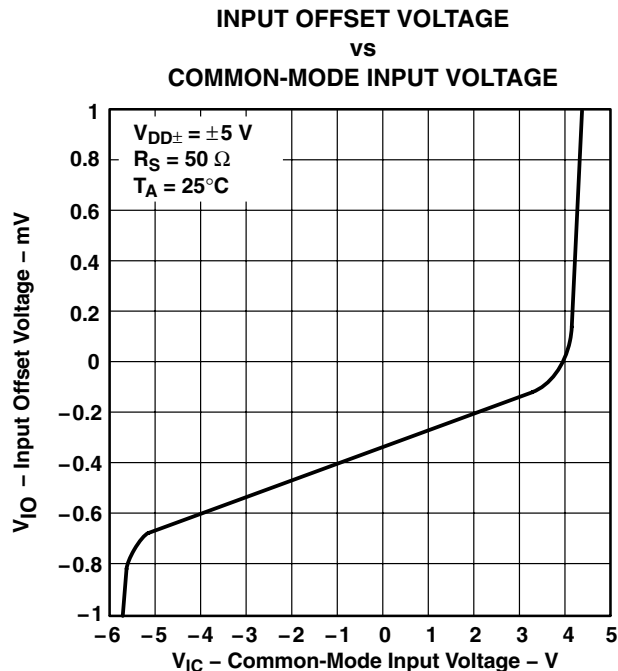


Figure 7

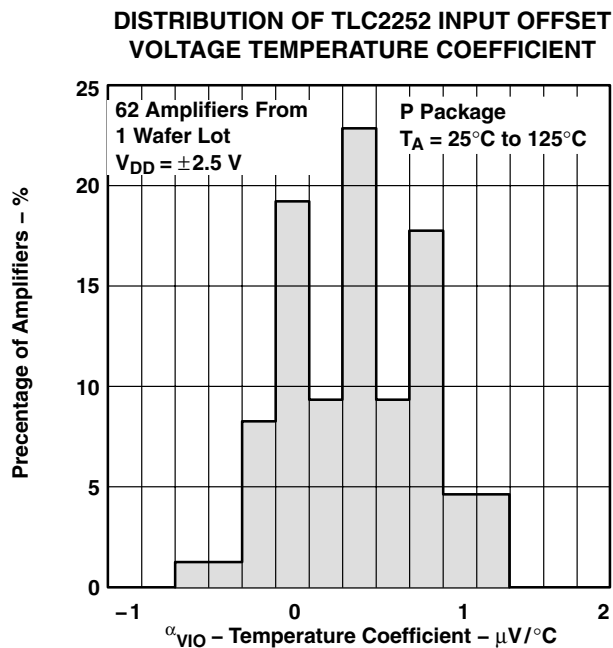


Figure 8

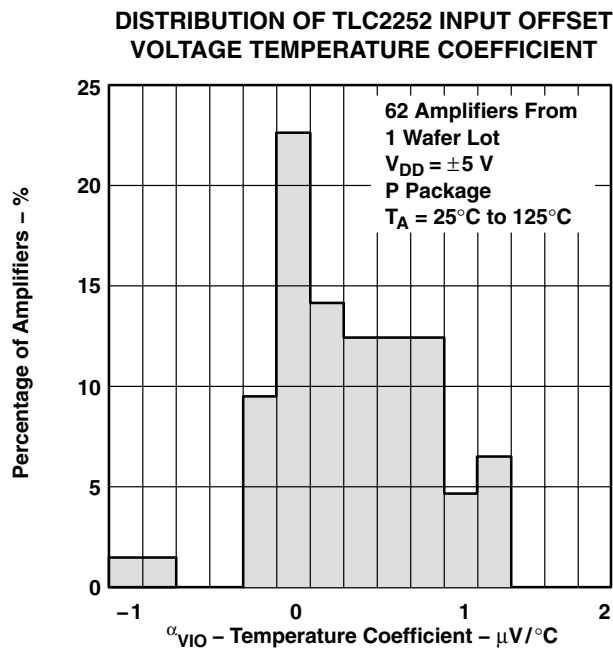


Figure 9

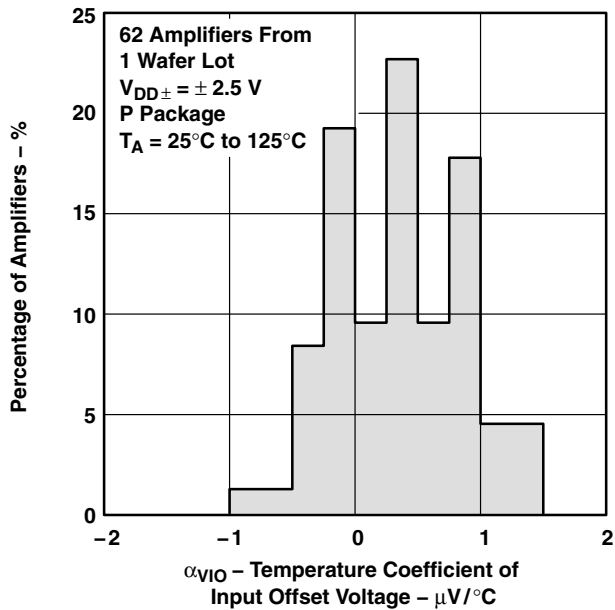
† For curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V.

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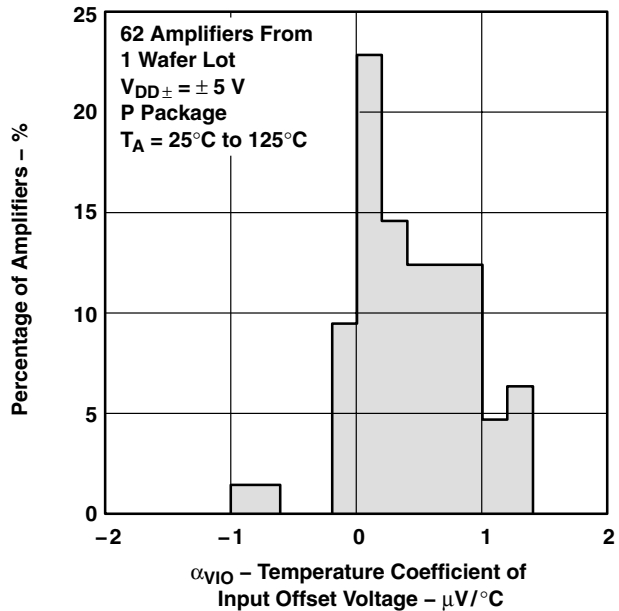
**TYPICAL CHARACTERISTICS**

**DISTRIBUTION OF TLC2254 INPUT OFFSET VOLTAGE TEMPERATURE COEFFICIENT**



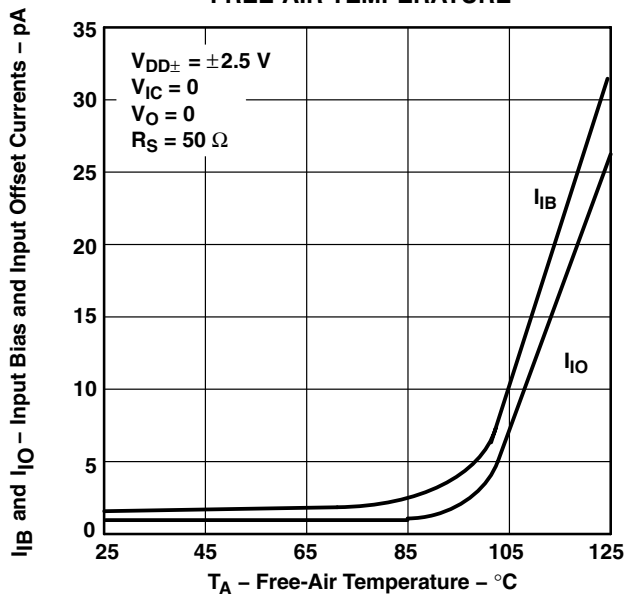
**Figure 10**

**DISTRIBUTION OF TLC2254 INPUT OFFSET VOLTAGE TEMPERATURE COEFFICIENT**



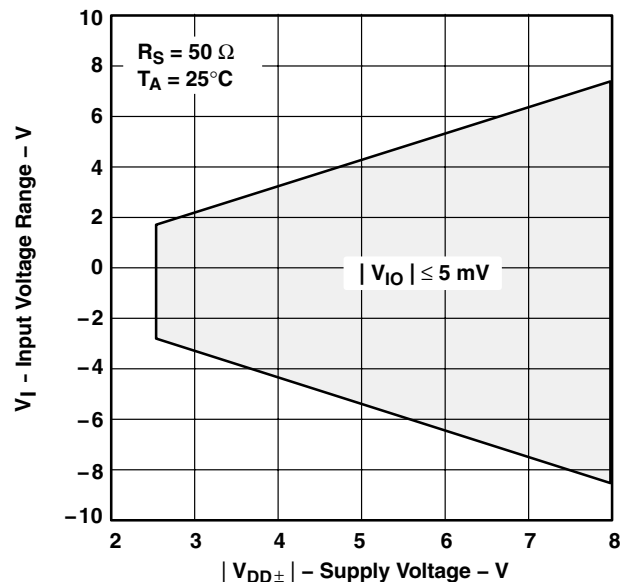
**Figure 11**

**INPUT BIAS AND INPUT OFFSET CURRENTS†**  
vs  
**FREE-AIR TEMPERATURE**



**Figure 12**

**INPUT VOLTAGE RANGE**  
vs  
**SUPPLY VOLTAGE**



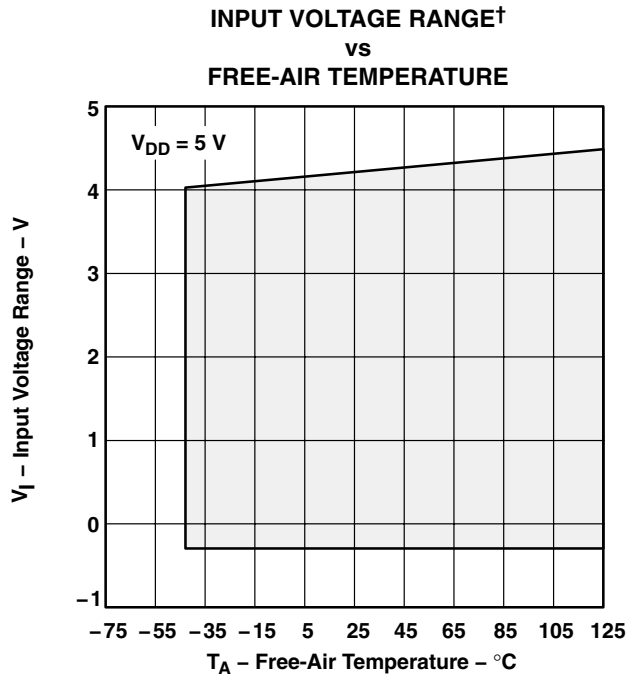
**Figure 13**

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

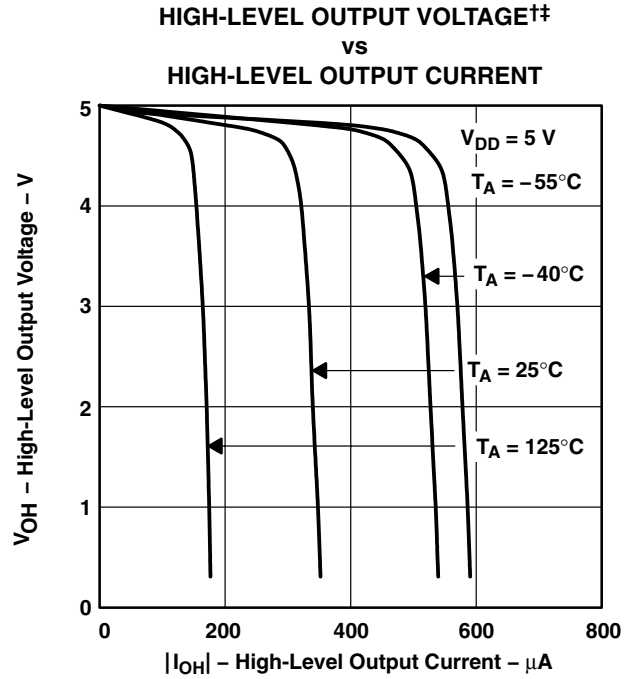




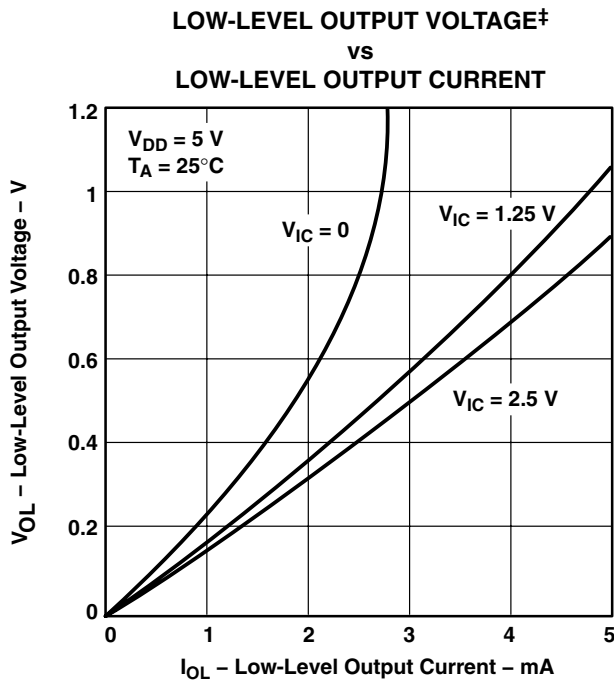
**TYPICAL CHARACTERISTICS**



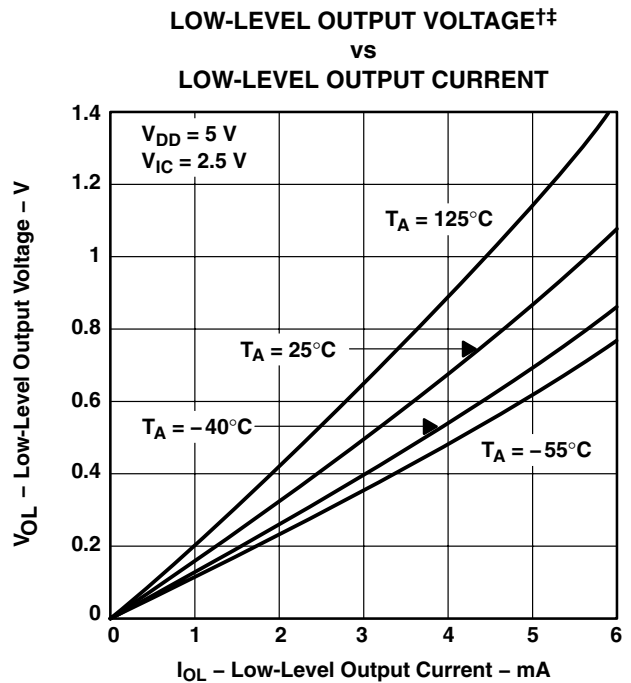
**Figure 14**



**Figure 15**



**Figure 16**



**Figure 17**

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

‡ For curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V.

# TLC225x-Q1, TLC225xA-Q1

## Advanced LinCMOS™ RAIL-TO-RAIL

### VERY LOW-POWER OPERATIONAL AMPLIFIERS

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#### TYPICAL CHARACTERISTICS

MAXIMUM POSITIVE PEAK OUTPUT VOLTAGE†  
vs  
OUTPUT CURRENT

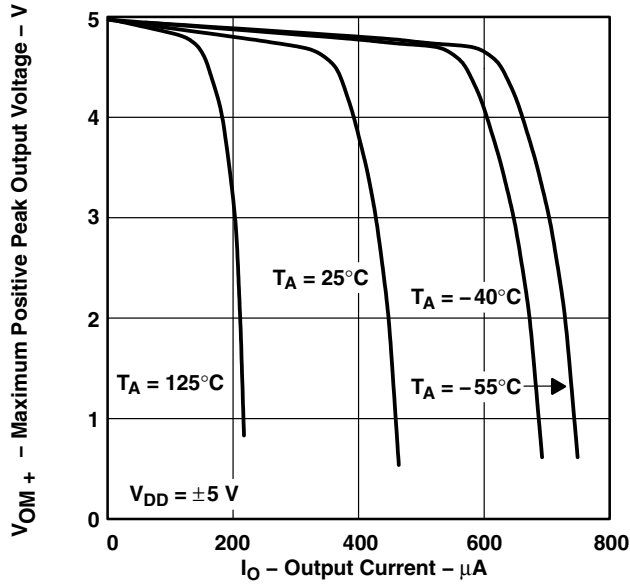


Figure 18

MAXIMUM NEGATIVE PEAK OUTPUT VOLTAGE†  
vs  
OUTPUT CURRENT

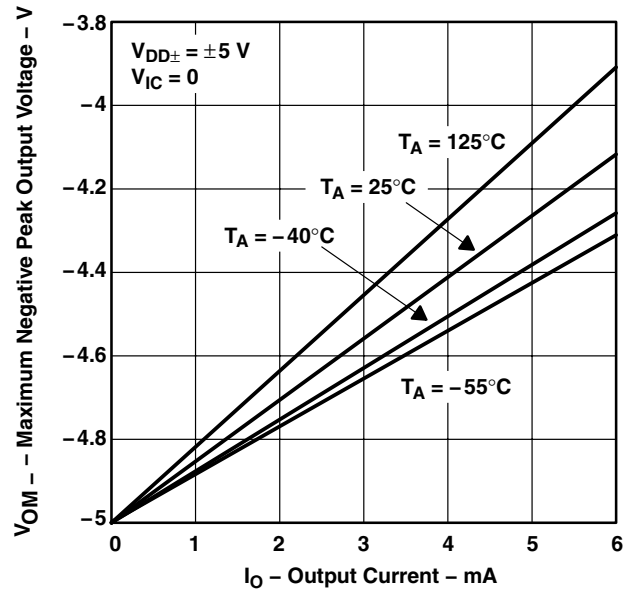


Figure 19

MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE‡  
vs  
FREQUENCY

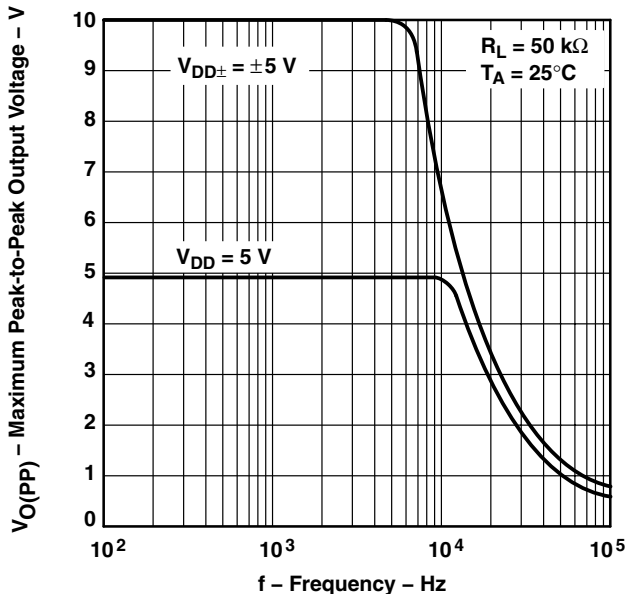


Figure 20

SHORT-CIRCUIT OUTPUT CURRENT  
vs  
SUPPLY VOLTAGE

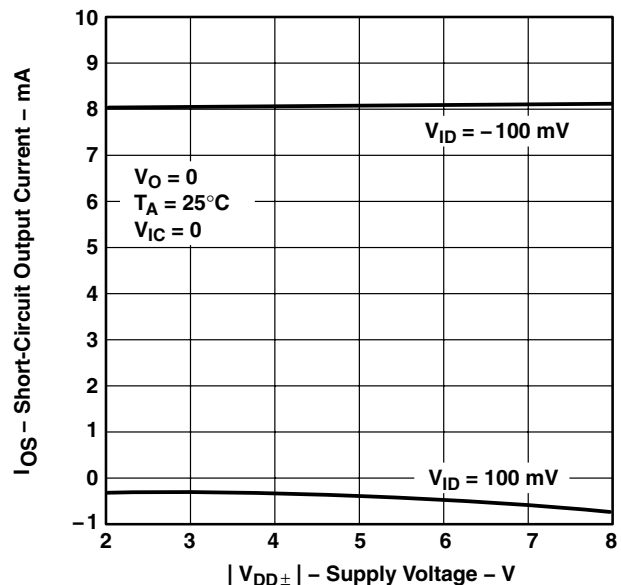


Figure 21

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

‡ For curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to  $2.5\text{ V}$ .



**TYPICAL CHARACTERISTICS**

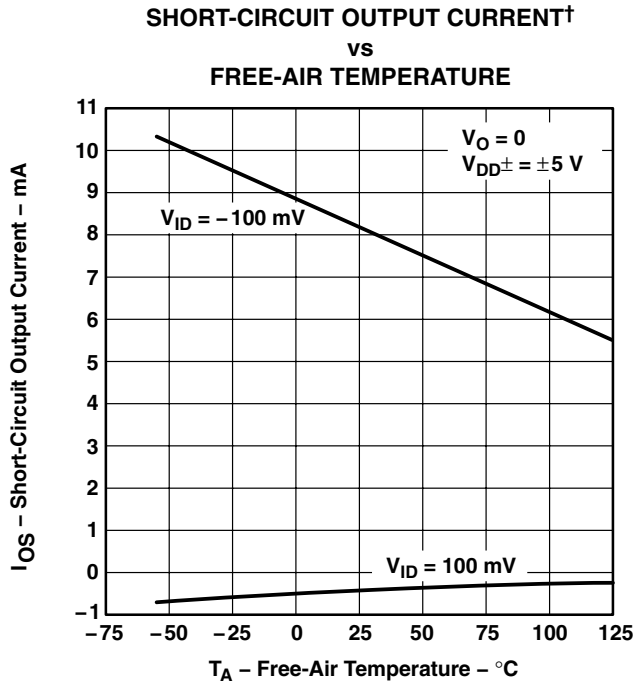


Figure 22

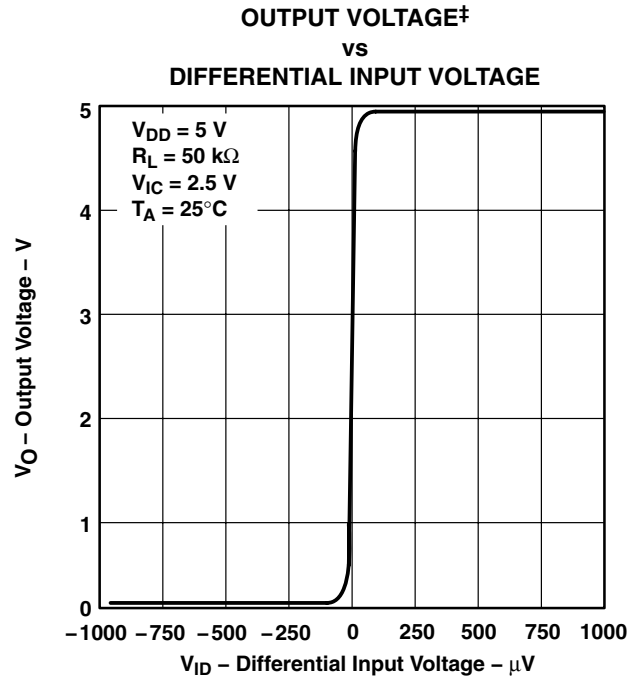


Figure 23

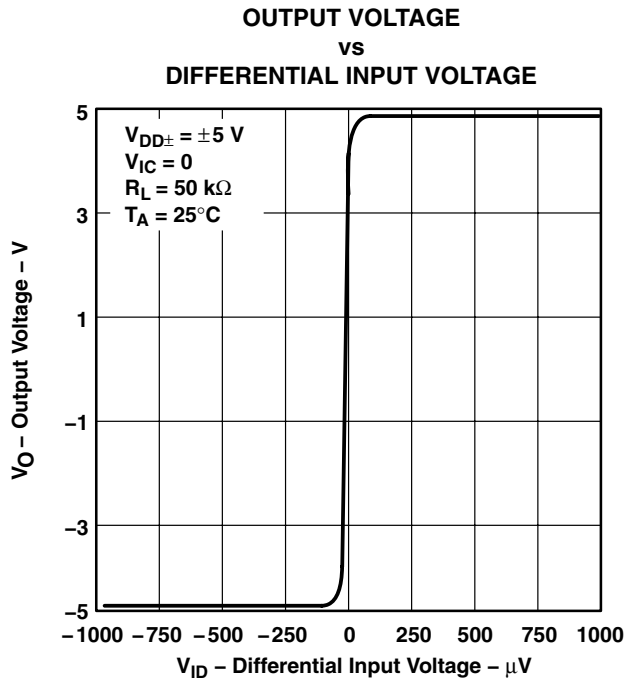


Figure 24

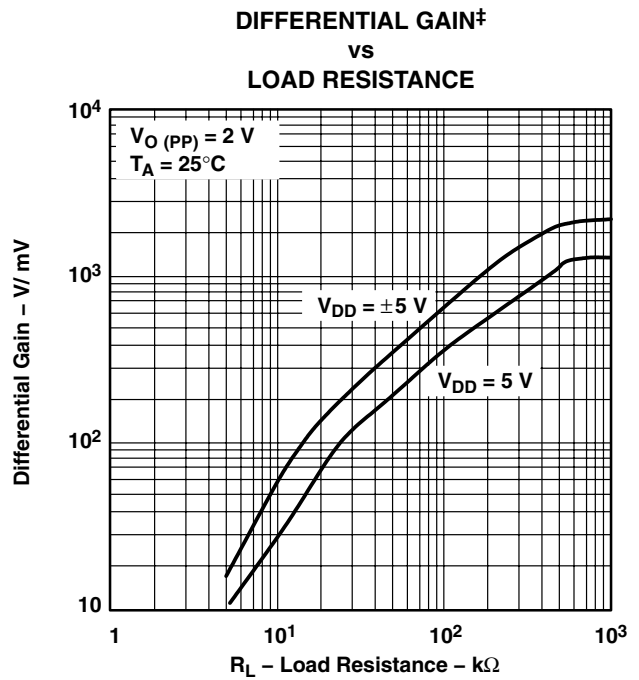


Figure 25

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

‡ For curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V.

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**TYPICAL CHARACTERISTICS**

**LARGE-SIGNAL DIFFERENTIAL VOLTAGE  
 AMPLIFICATION AND PHASE MARGIN†  
 vs  
 FREQUENCY**

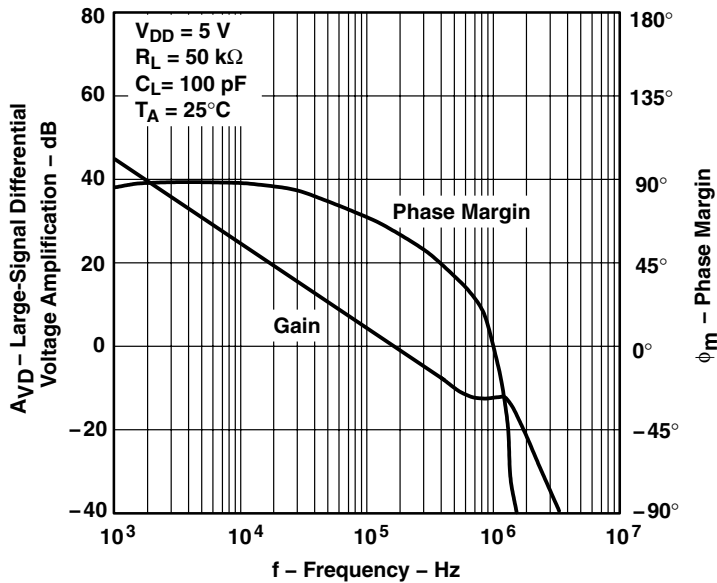


Figure 26

**LARGE-SIGNAL DIFFERENTIAL VOLTAGE  
 AMPLIFICATION AND PHASE MARGIN  
 vs  
 FREQUENCY**

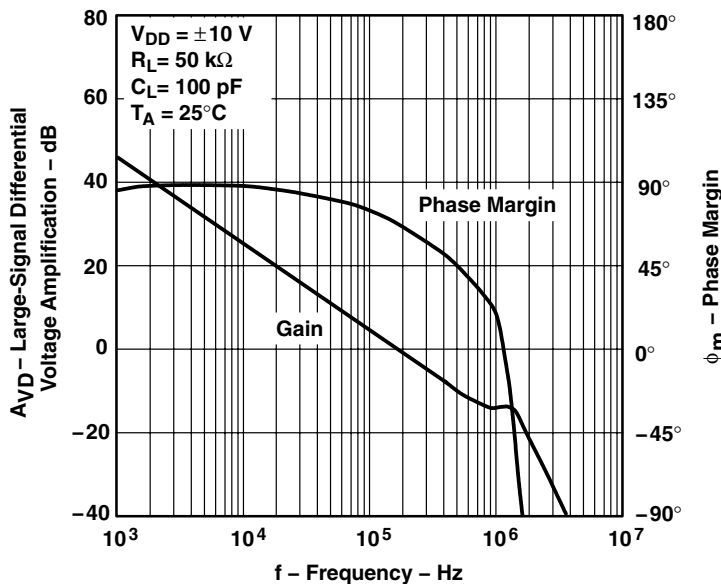
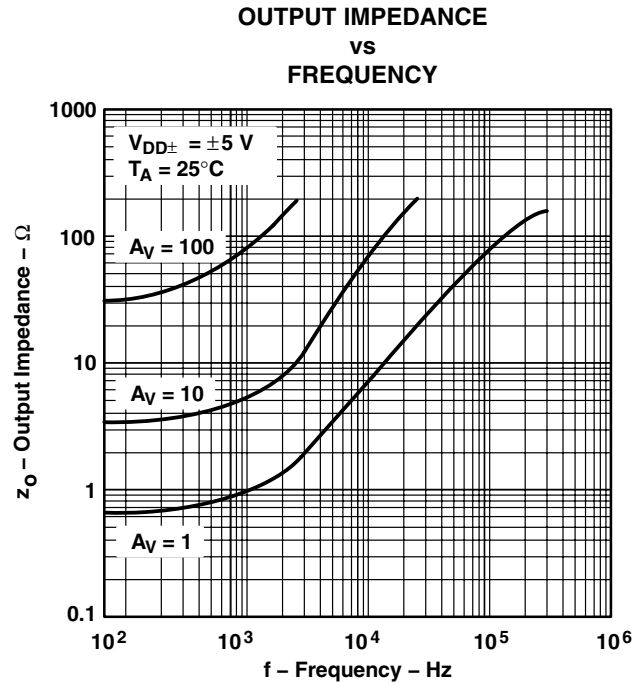
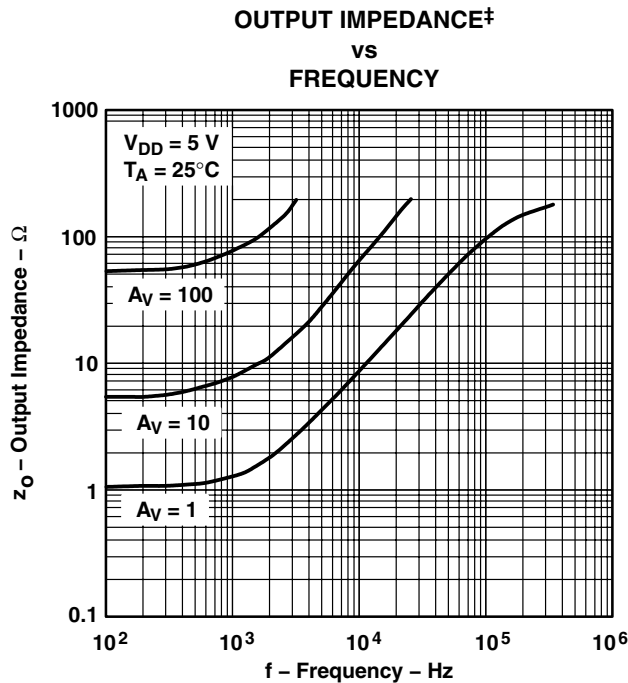
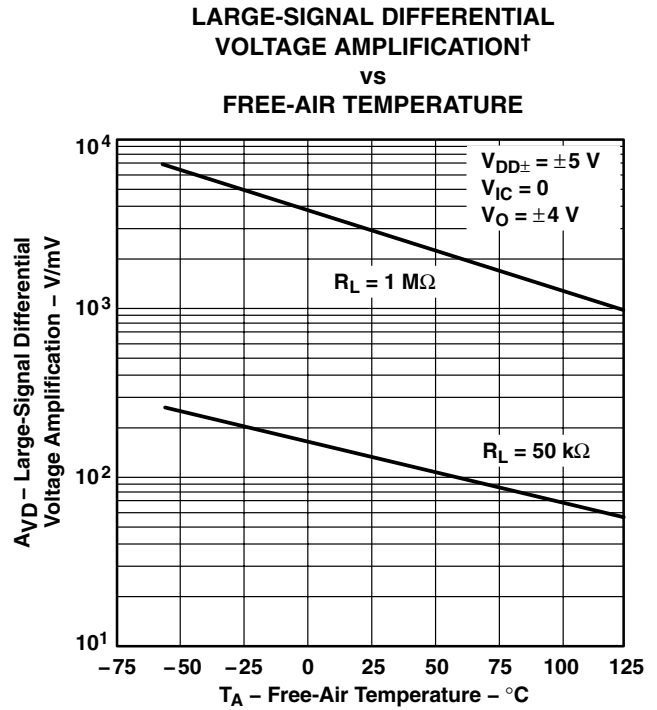
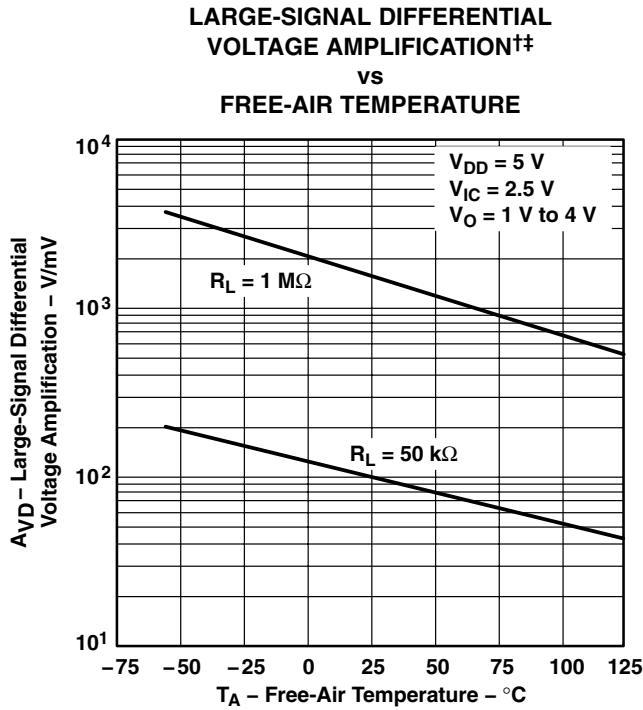


Figure 27

† For curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V.



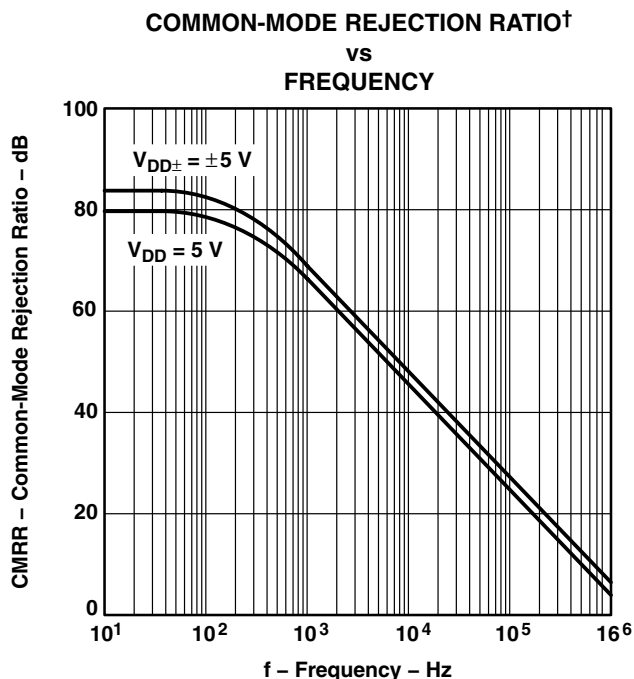
TYPICAL CHARACTERISTICS



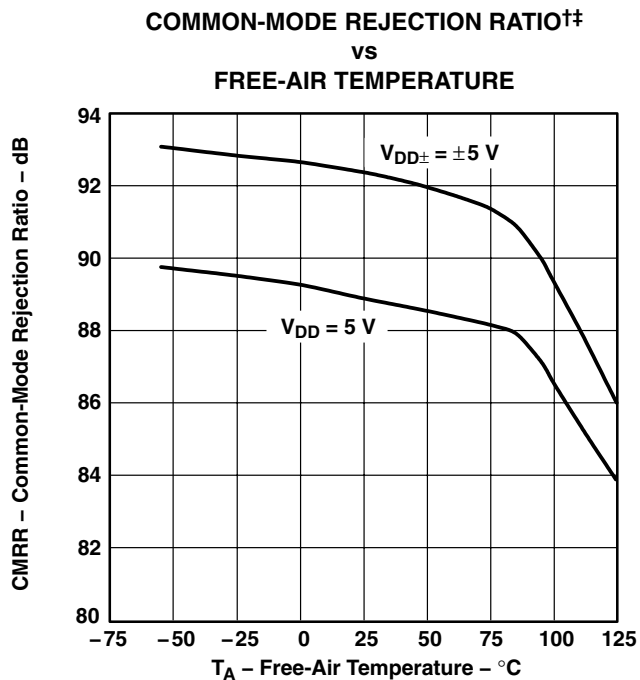
† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

‡ For curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V.

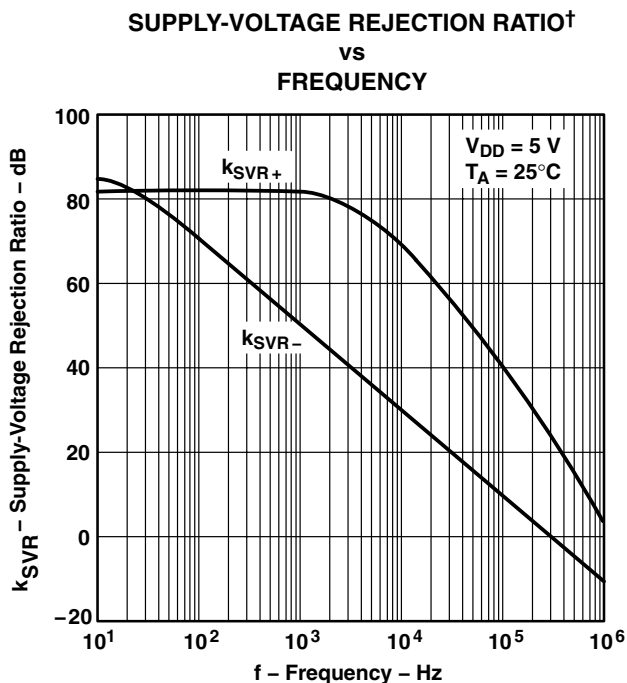
**TYPICAL CHARACTERISTICS**



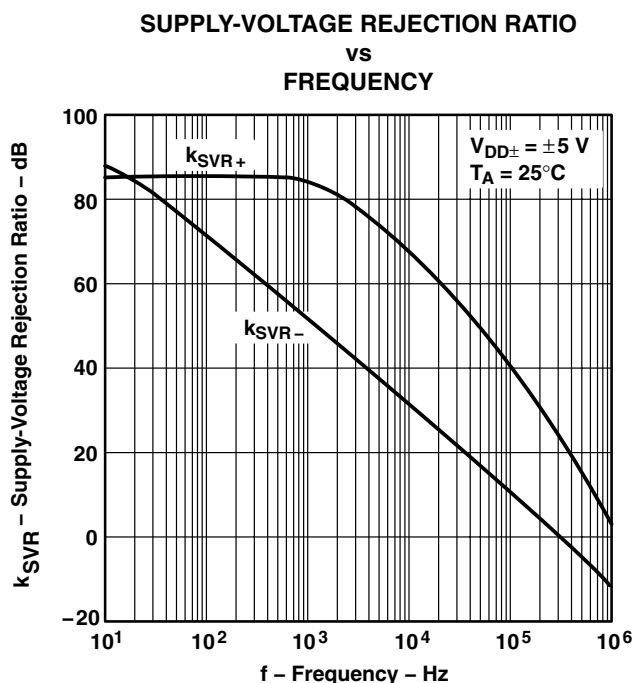
**Figure 32**



**Figure 33**



**Figure 34**



**Figure 35**

† For curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V.

‡ Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



TYPICAL CHARACTERISTICS

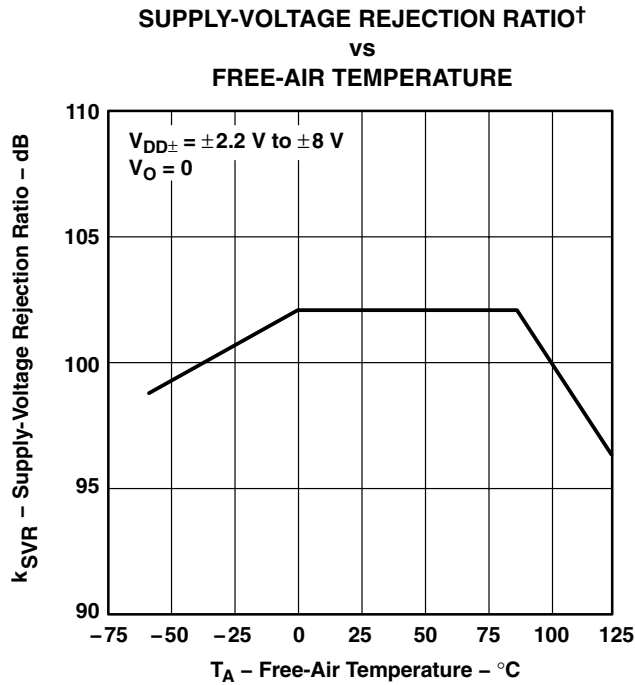


Figure 36

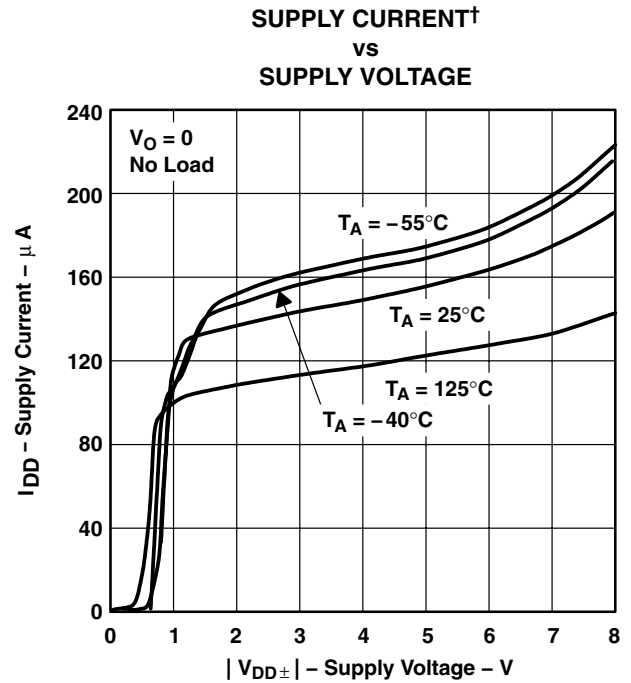


Figure 37

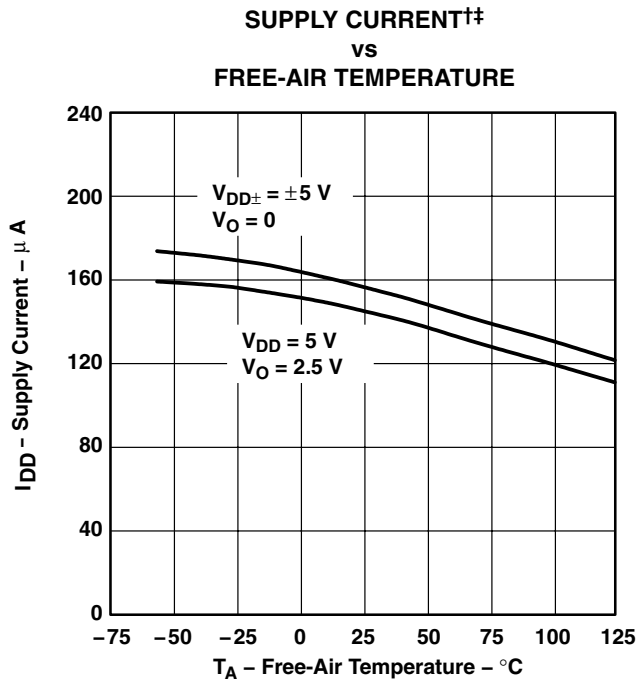


Figure 38

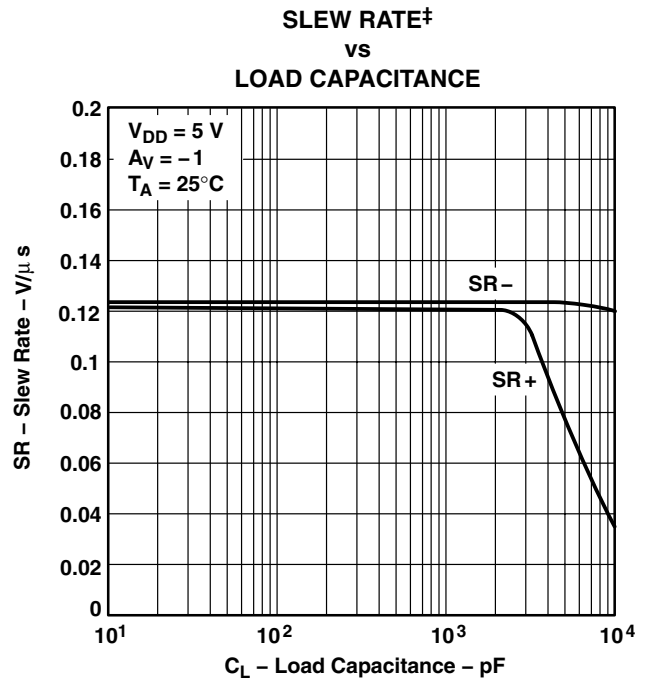


Figure 39

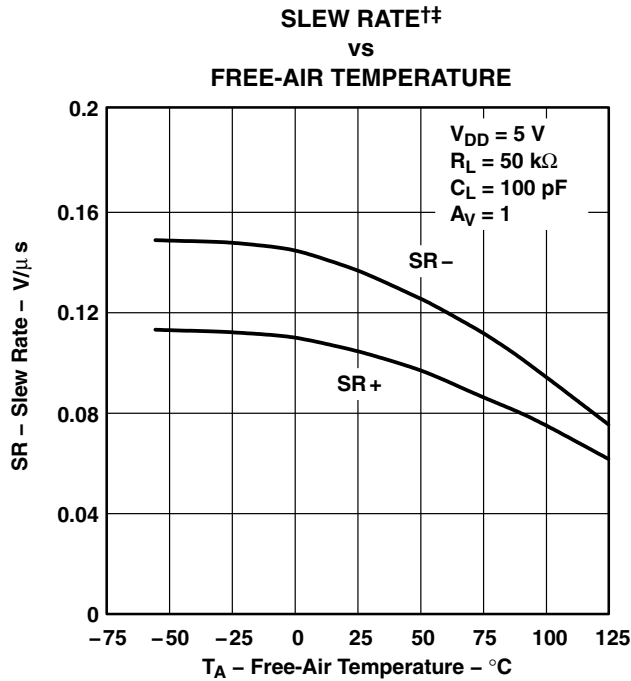
† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

‡ For curves where  $V_{DD} = 5 \text{ V}$ , all loads are referenced to 2.5 V.

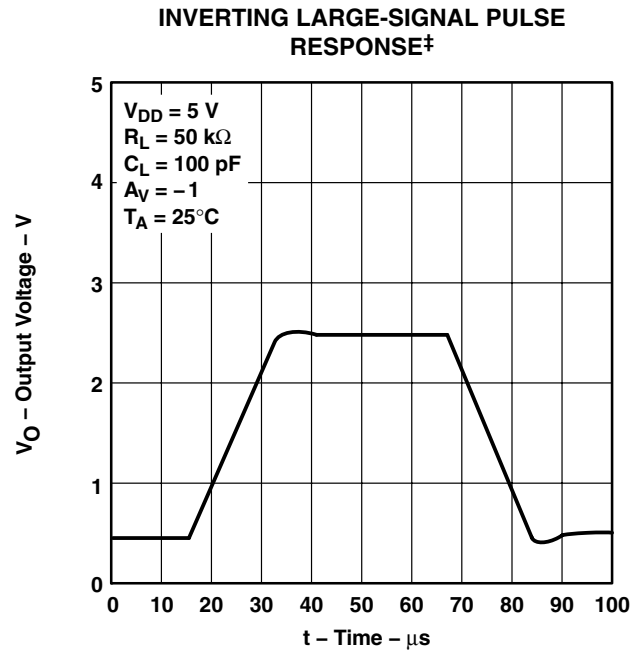
**TLC225x-Q1, TLC225xA-Q1**  
**Advanced LinCMOS™ RAIL-TO-RAIL**  
**VERY LOW-POWER OPERATIONAL AMPLIFIERS**

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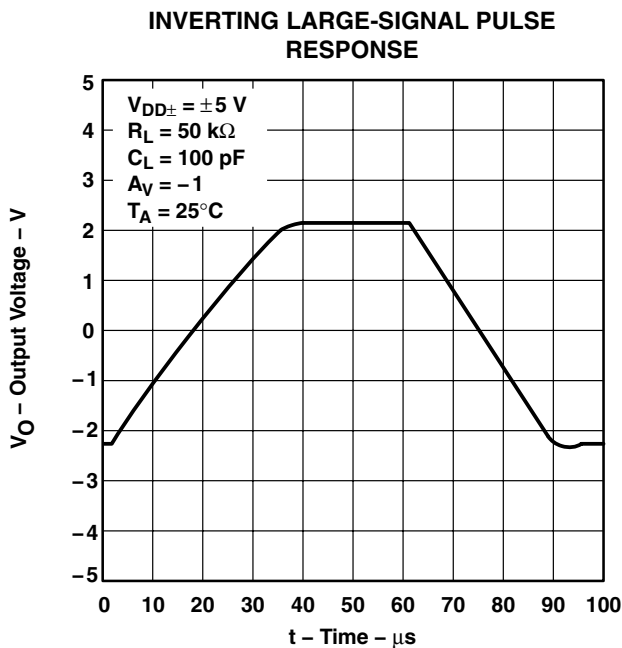
**TYPICAL CHARACTERISTICS**



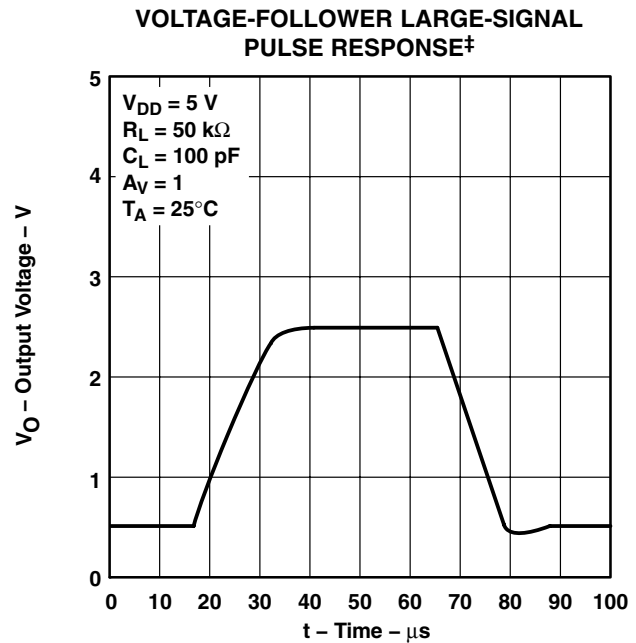
**Figure 40**



**Figure 41**



**Figure 42**



**Figure 43**

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

‡ For curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V.





TYPICAL CHARACTERISTICS

VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE

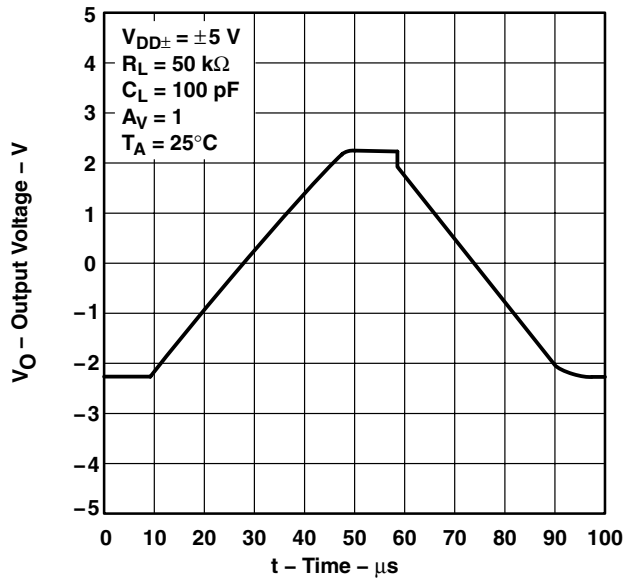


Figure 44

INVERTING SMALL-SIGNAL PULSE RESPONSE†

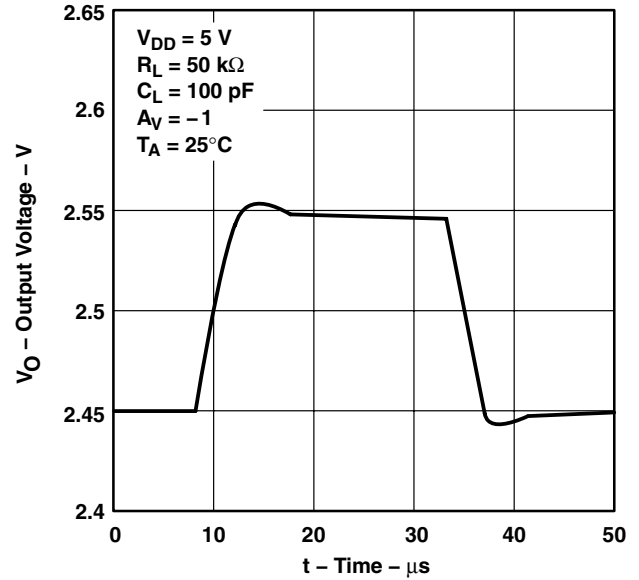


Figure 45

INVERTING SMALL-SIGNAL PULSE RESPONSE

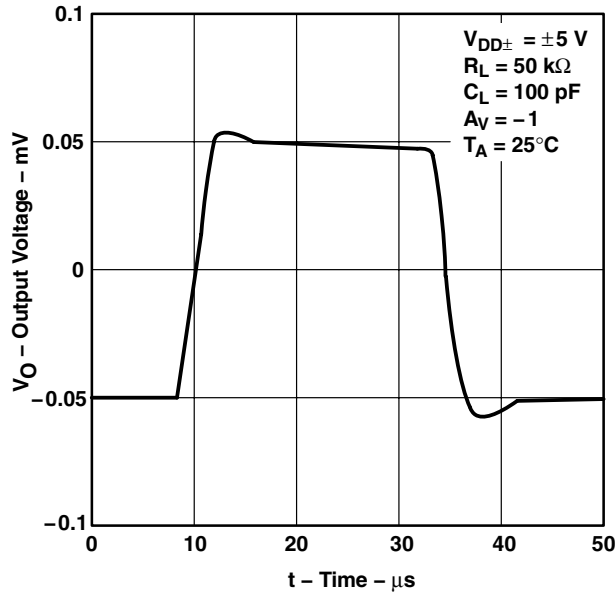


Figure 46

VOLTAGE-FOLLOWER SMALL-SIGNAL PULSE RESPONSE†

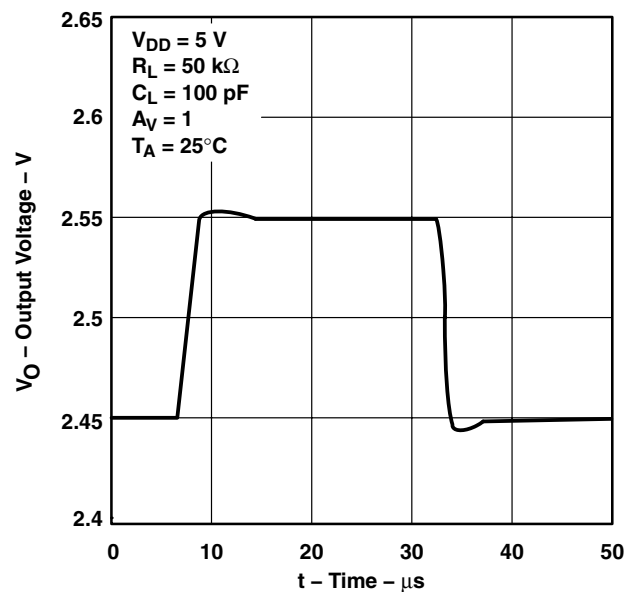


Figure 47

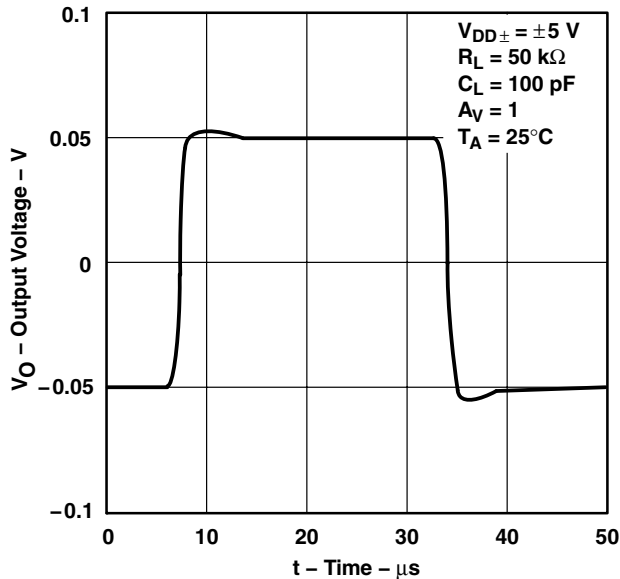
† For curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V.

**TLC225x-Q1, TLC225xA-Q1**  
**Advanced LinCMOS™ RAIL-TO-RAIL**  
**VERY LOW-POWER OPERATIONAL AMPLIFIERS**

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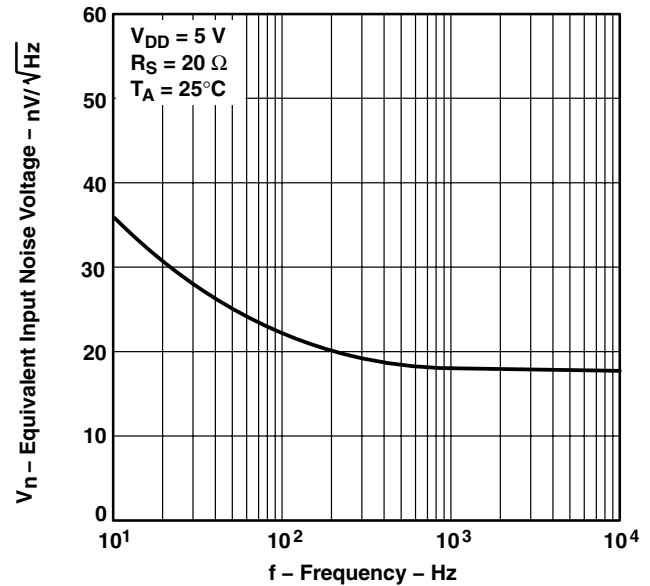
**TYPICAL CHARACTERISTICS**

**VOLTAGE-FOLLOWER SMALL-SIGNAL PULSE RESPONSE**



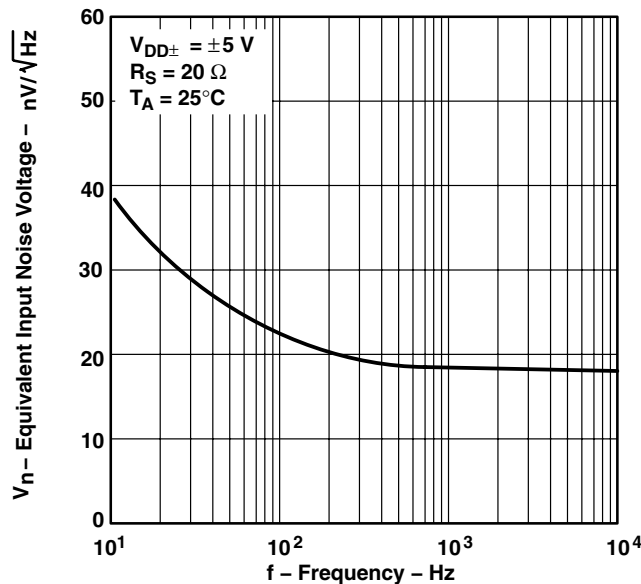
**Figure 48**

**EQUIVALENT INPUT NOISE VOLTAGE† vs FREQUENCY**



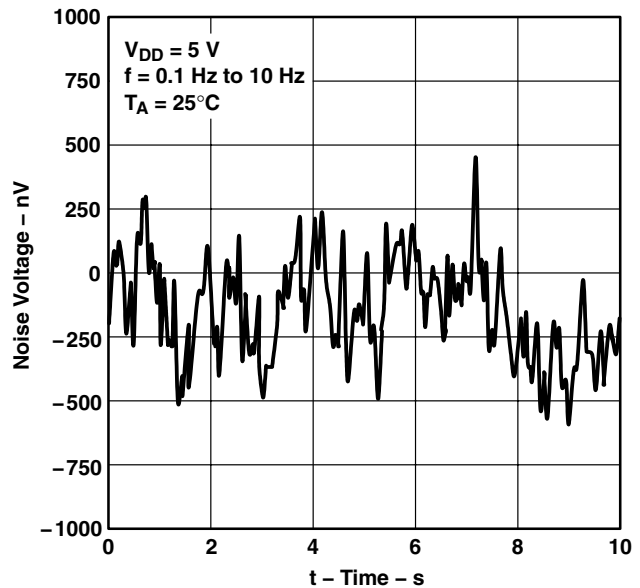
**Figure 49**

**EQUIVALENT INPUT NOISE VOLTAGE vs FREQUENCY**



**Figure 50**

**EQUIVALENT INPUT NOISE VOLTAGE OVER A 10-SECOND PERIOD†**

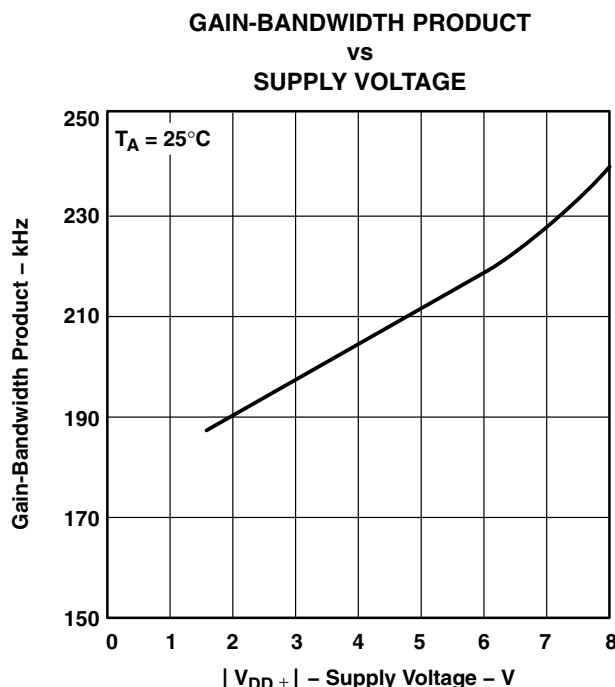
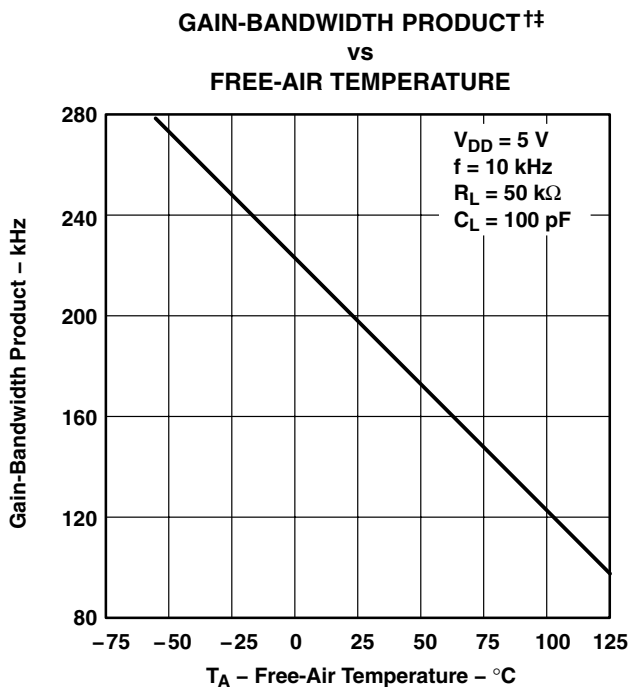
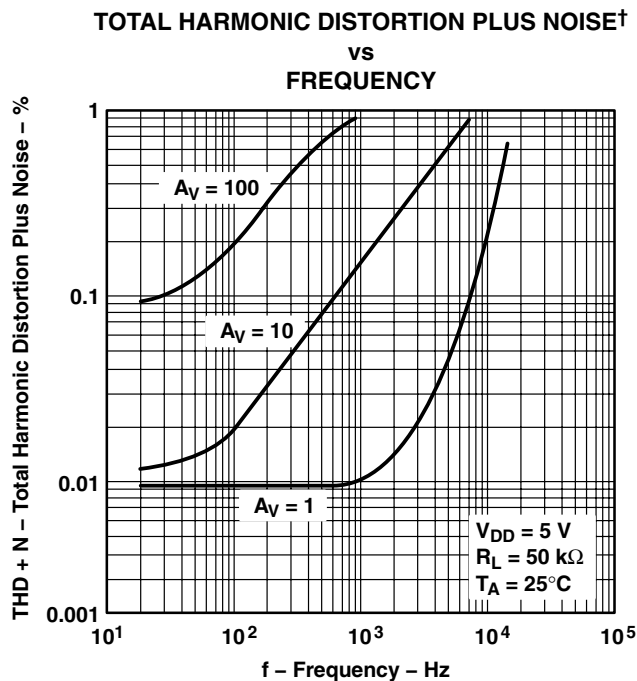
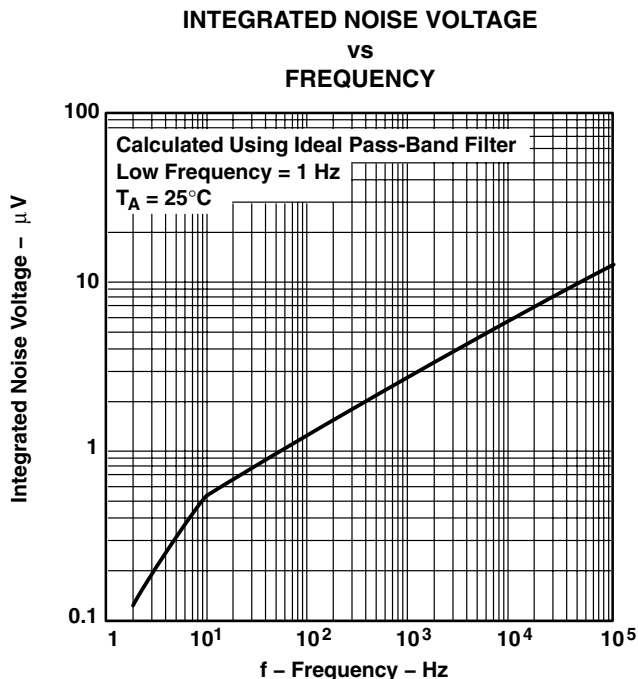


**Figure 51**

† For curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V.



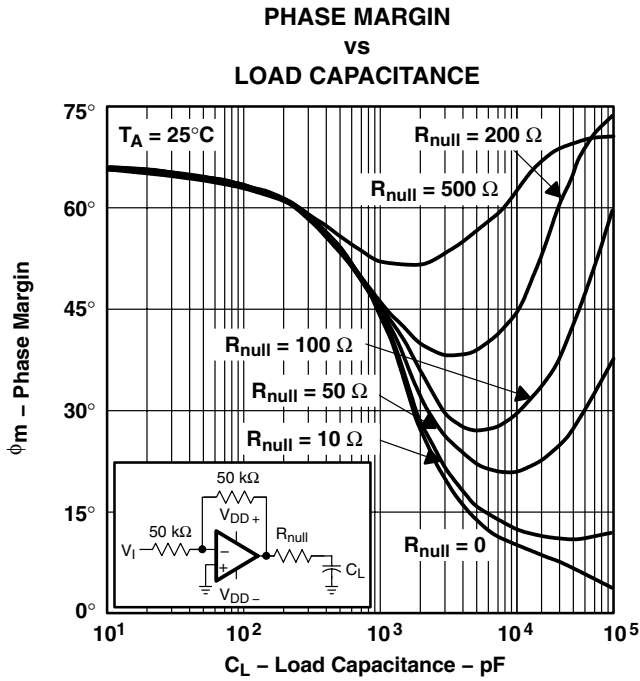
**TYPICAL CHARACTERISTICS**



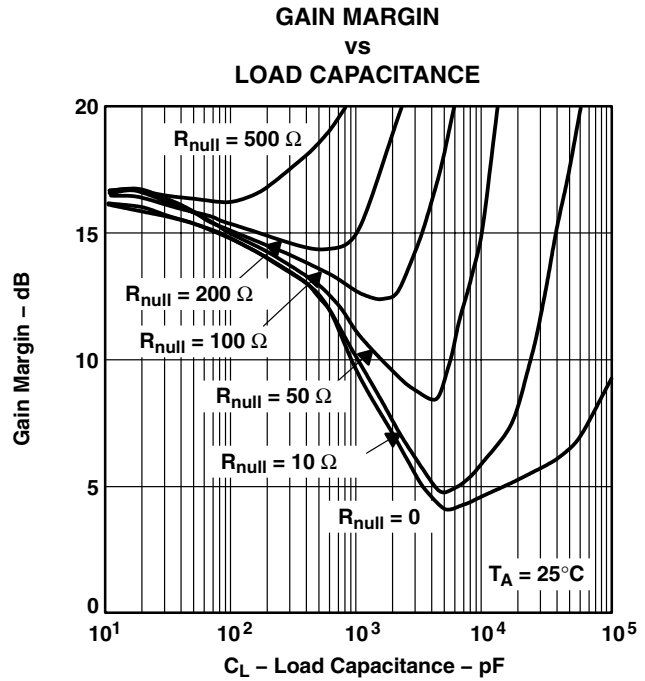
† For curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to  $2.5\text{ V}$ .

‡ Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

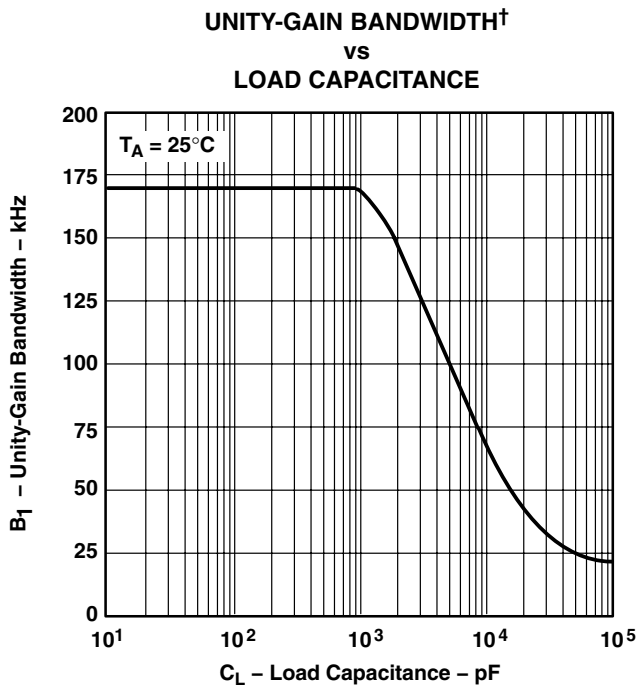
**TYPICAL CHARACTERISTICS**



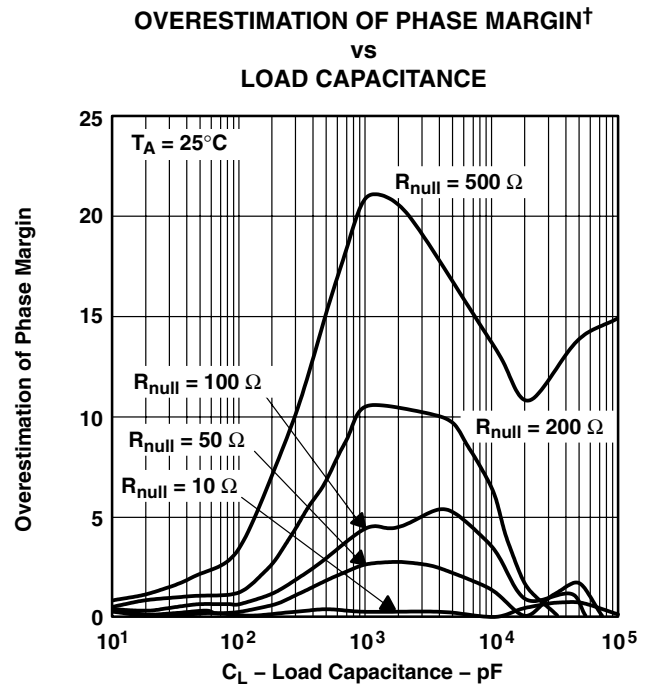
**Figure 56**



**Figure 57**



**Figure 58**



**Figure 59**

† See application information

## APPLICATION INFORMATION

### driving large capacitive loads

The TLC225x is designed to drive larger capacitive loads than most CMOS operational amplifiers. Figure 56 and Figure 57 illustrate its ability to drive loads up to 1000 pF while maintaining good gain and phase margins ( $R_{null} = 0$ ).

A smaller series resistor ( $R_{null}$ ) at the output of the device (see Figure 60) improves the gain and phase margins when driving large capacitive loads. Figure 56 and Figure 57 show the effects of adding series resistances of 10  $\Omega$ , 50  $\Omega$ , 100  $\Omega$ , 200  $\Omega$ , and 500  $\Omega$ . The addition of this series resistor has two effects: the first is that it adds a zero to the transfer function and the second is that it reduces the frequency of the pole associated with the output load in the transfer function.

The zero introduced to the transfer function is equal to the series resistance times the load capacitance. To calculate the improvement in phase margin, equation 1 can be used.

$$\Delta\phi_{m1} = \tan^{-1} \left( 2 \times \pi \times \text{UGBW} \times R_{null} \times C_L \right) \quad (1)$$

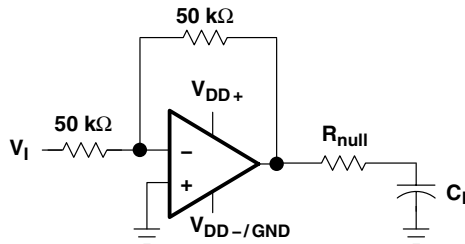
Where :

- $\Delta\phi_{m1}$  = Improvement in phase margin
- UGBW = Unity-gain bandwidth frequency
- $R_{null}$  = Output series resistance
- $C_L$  = Load capacitance

The unity-gain bandwidth (UGBW) frequency decreases as the capacitive load increases (see Figure 58). To use equation 1, UGBW must be approximated from Figure 58.

Using equation 1 alone overestimates the improvement in phase margin, as illustrated in Figure 59. The overestimation is caused by the decrease in the frequency of the pole associated with the load, thus providing additional phase shift and reducing the overall improvement in phase margin.

Using Figure 60, with equation 1 enables the designer to choose the appropriate output series resistance to optimize the design of circuits driving large capacitance loads.



**Figure 60. Series-Resistance Circuit**

# TLC225x-Q1, TLC225xA-Q1 Advanced LinCMOS™ RAIL-TO-RAIL VERY LOW-POWER OPERATIONAL AMPLIFIERS

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## APPLICATION INFORMATION

### macromodel information

Macromodel information provided was derived using MicroSim *Parts*™, the model generation software used with MicroSim *PSPice*™. The Boyle macromodel (see Note 5) and subcircuit in Figure 61 are generated using the TLC225x typical electrical and operating characteristics at  $T_A = 25^\circ\text{C}$ . Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification
- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

NOTE 4: G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Integrated Circuit Operational Amplifiers", *IEEE Journal of Solid-State Circuits*, SC-9, 353 (1974).

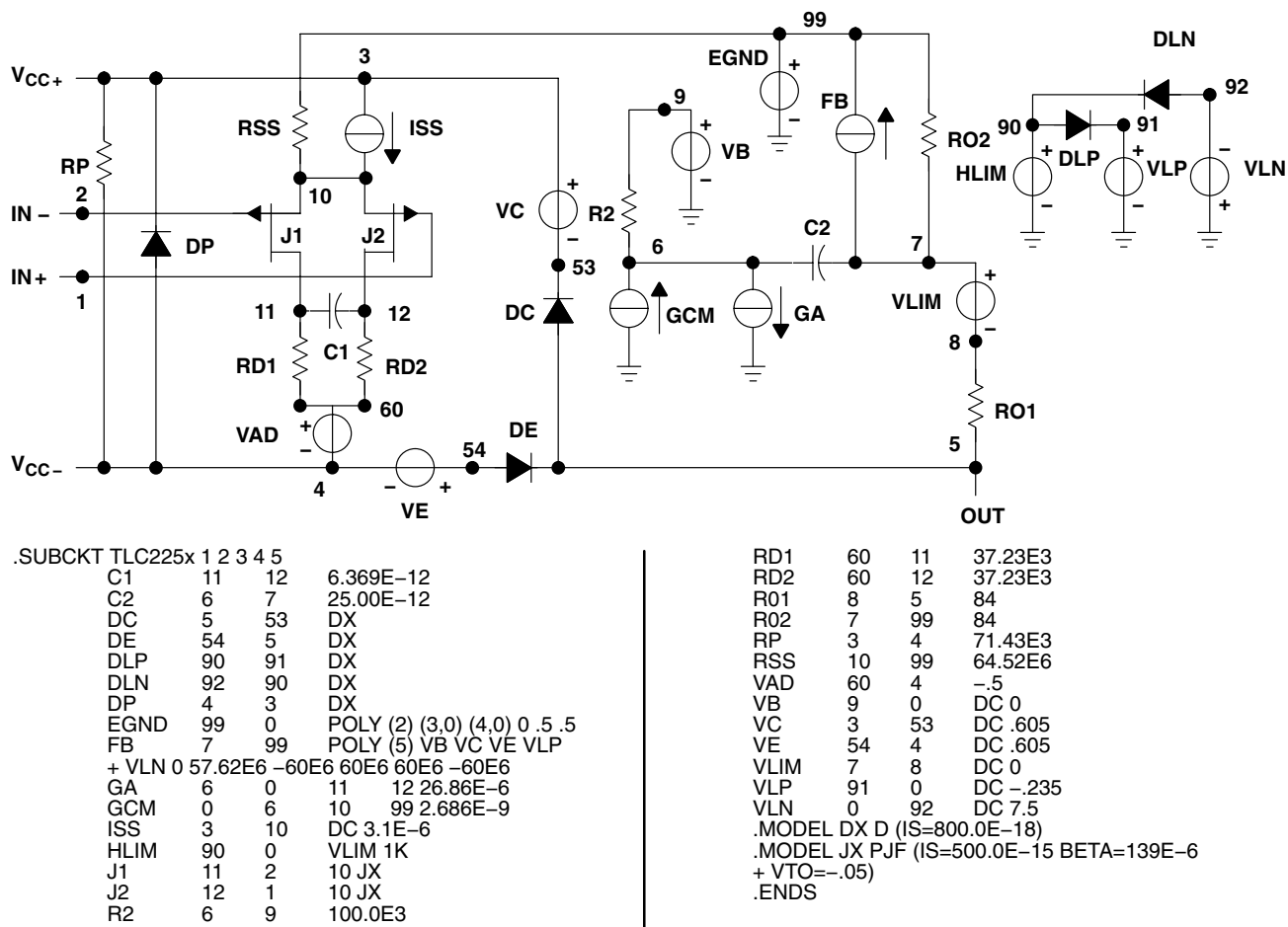


Figure 61. Boyle Macromodel and Subcircuit

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POST OFFICE BOX 655303 • DALLAS, TEXAS 75265  
POST OFFICE BOX 1443 • HOUSTON, TEXAS 77251-1443

## PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TLC2252AQDRG4Q1	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2252AQ	<a href="#">Samples</a>
TLC2252AQDRQ1	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2252AQ	<a href="#">Samples</a>
TLC2252AQPWRG4Q1	ACTIVE	TSSOP	PW	8	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2252AQ	<a href="#">Samples</a>
TLC2254AQPWRQ1	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2254AQ	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**OTHER QUALIFIED VERSIONS OF TLC2252A-Q1, TLC2254A-Q1 :**

- Catalog : [TLC2252A](#), [TLC2254A](#)
- Enhanced Product : [TLC2252A-EP](#), [TLC2254A-EP](#)
- Military : [TLC2252AM](#), [TLC2254AM](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Enhanced Product - Supports Defense, Aerospace and Medical Applications
- Military - QML certified for Military and Defense Applications



**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLC2252AQPWRG4Q1	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
TLC2254AQPWRQ1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

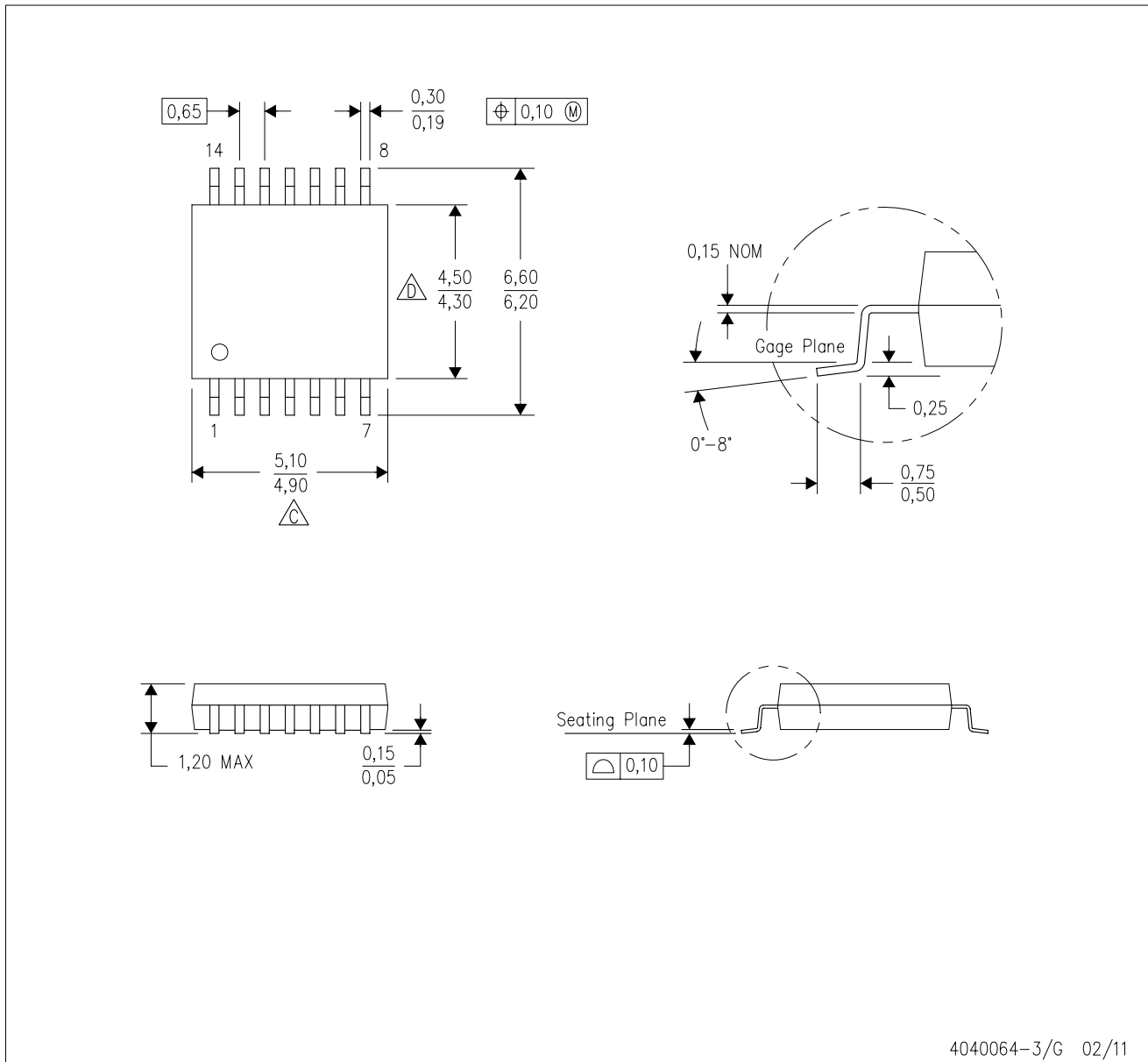
**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLC2252AQPWRG4Q1	TSSOP	PW	8	2000	356.0	356.0	35.0
TLC2254AQPWRQ1	TSSOP	PW	14	2000	356.0	356.0	35.0

PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
  - B. This drawing is subject to change without notice.
  - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
  - D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
  - E. Falls within JEDEC MO-153

PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Publication IPC-7351 is recommended for alternate designs.
  - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

# D0008A



## PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



**NOTES:**

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

# EXAMPLE BOARD LAYOUT

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

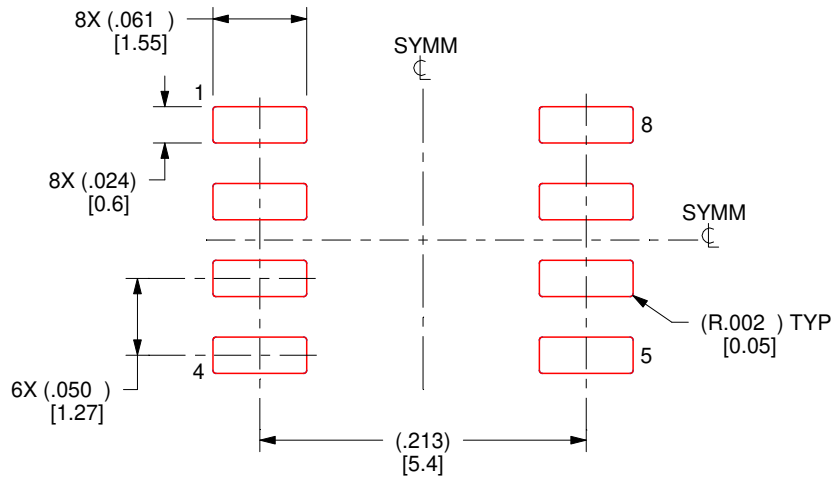
- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

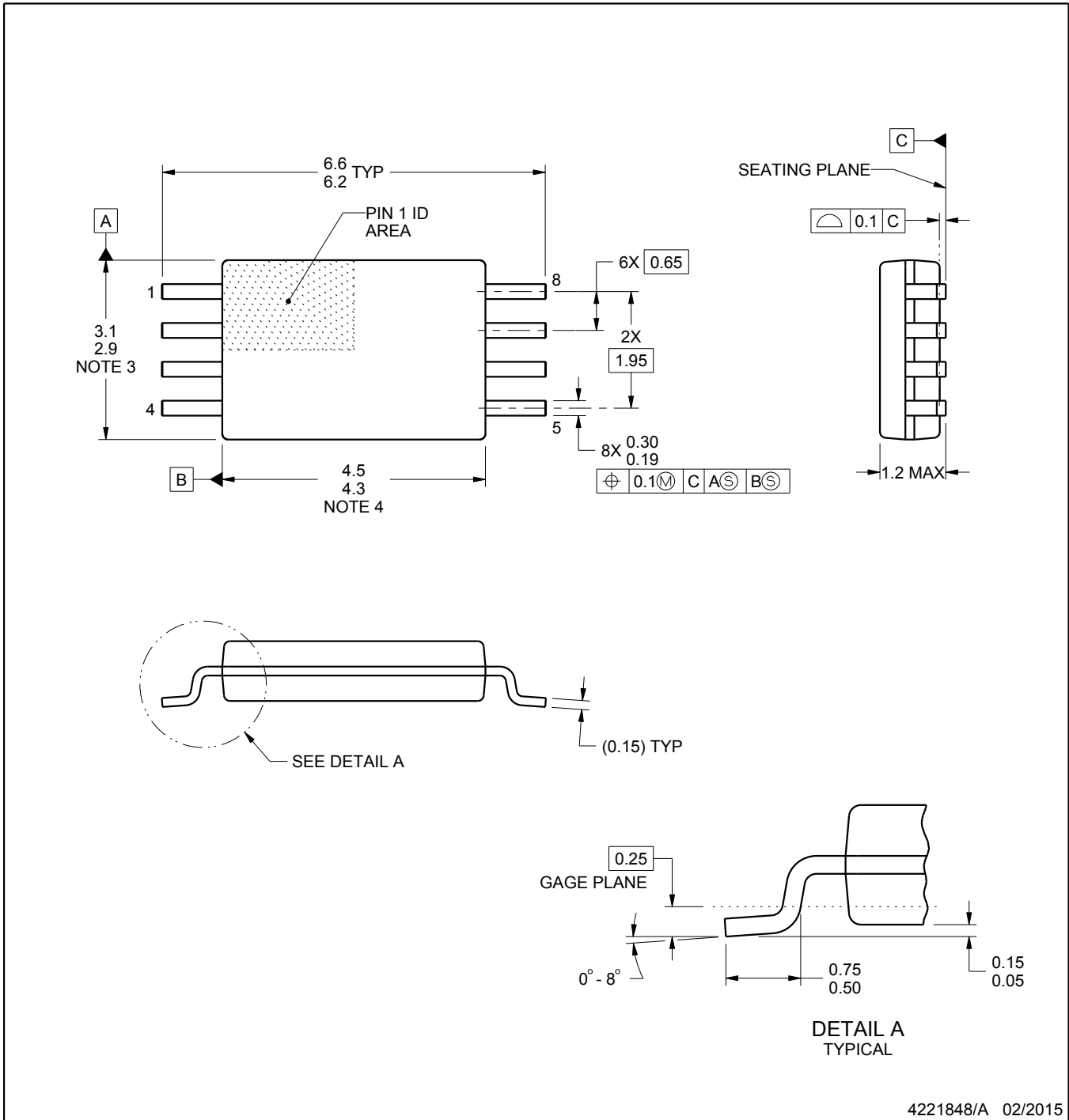


SOLDER PASTE EXAMPLE  
BASED ON .005 INCH [0.125 MM] THICK STENCIL  
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.



NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153, variation AA.

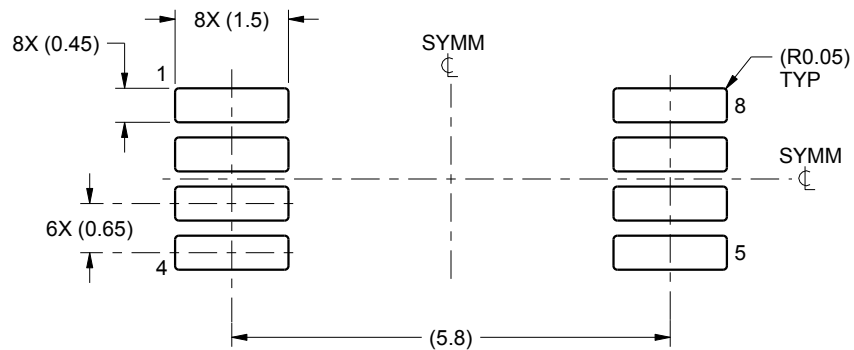


# EXAMPLE BOARD LAYOUT

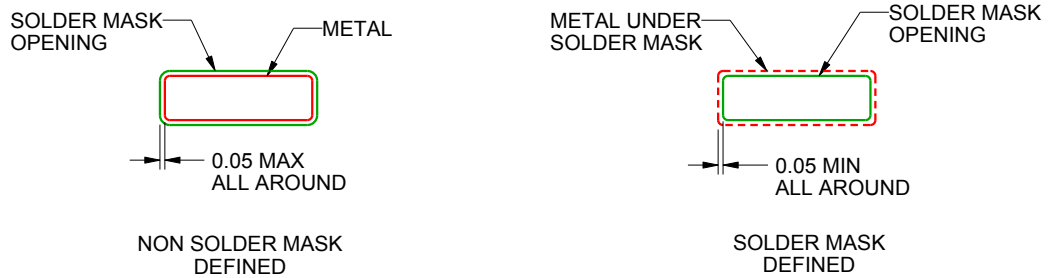
PW0008A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
SCALE:10X



SOLDER MASK DETAILS  
NOT TO SCALE

4221848/A 02/2015

NOTES: (continued)

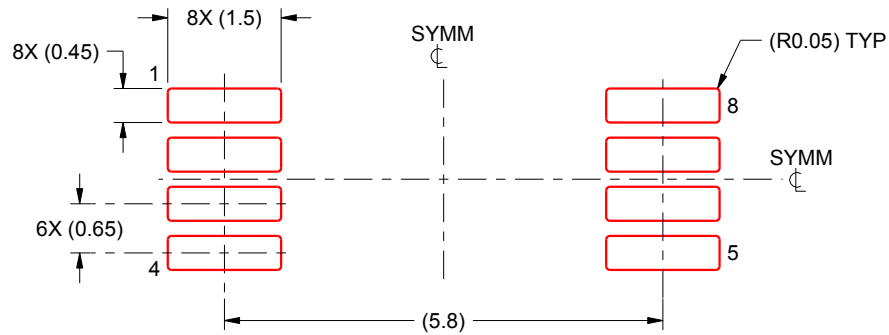
- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

PW0008A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:10X

4221848/A 02/2015

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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